

LM6171 High-Speed, Low-Power, Low-Distortion Voltage Feedback Amplifier

1 Features

- Typical unless otherwise noted
- Easy-to-use voltage feedback topology
- Very high slew rate: 3600 V/ μ s
- Wide unity-gain-bandwidth product: 76 MHz
- -3 -dB frequency at $A_V = +2$: 75 MHz
- Low supply current: 2.5 mA
- High CMRR: 110 dB
- High open-loop gain: 90 dB
- Specified for ± 15 -V and ± 5 -V operation

2 Applications

- Multimedia broadcast systems
- Line driver, switch
- Video amplifier
- NTSC, PAL[®] and SECAM systems
- ADC/DAC buffer
- HDTV amplifier
- Pulse amplifier and peak detector
- Instrumentation amplifier
- Active filter

3 Description

The LM6171 is a high-speed, unity-gain-stable voltage-feedback amplifier. The LM6171 offers a high slew rate of 3600 V/ μ s and a unity-gain bandwidth of 100 MHz while consuming only 2.5 mA of supply current. The LM6171 has very impressive ac and dc performance that is a great benefit for high-speed signal processing and video applications.

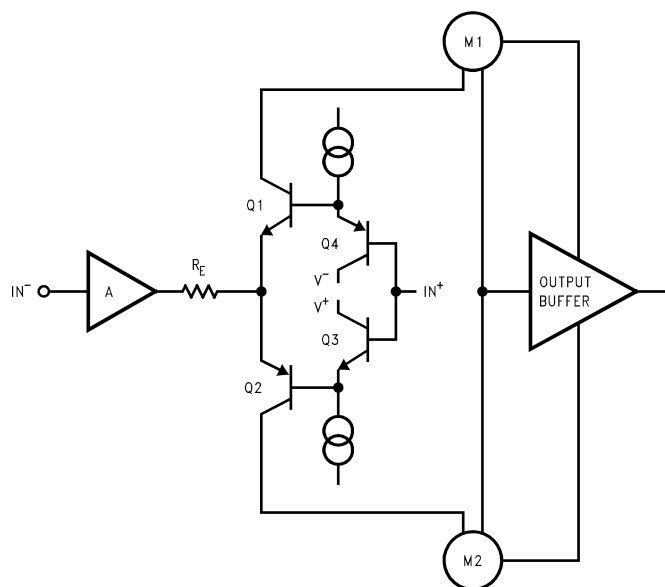
The ± 15 -V power supplies allow for large signal swings and give greater dynamic range and signal-to-noise ratio (SNR). The LM6171 has a high output current drive, low spurious-free dynamic range (SFDR) and total harmonic distortion (THD), and is an excellent choice for analog-to-digital converter (ADC) and digital-to-analog converter (DAC) systems. The LM6171 is specified for ± 5 -V operation for portable applications.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾
LM6171	D (SOIC, 8)	4.9 mm \times 6 mm
	P (PDIP, 8)	9.81 mm \times 9.43 mm

(1) For more information, see [Section 10](#).

(2) The package size (length \times width) is a nominal value and includes pins, where applicable.



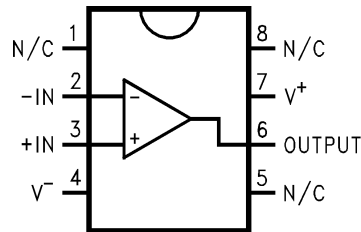
Simplified Schematic



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4 Pin Configuration and Functions



**Figure 4-1. D Package, 8-Pin SOIC
P Package, 8-Pin PDIP
(Top View)**

Table 4-1. Pin Functions

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
-IN	2	I	Negative input pin
+IN	3	I	Positive input pin
N/C	1, 5, 8	—	This pin is not internally connected; leave floating or connect to any other pin on the device.
OUTPUT	6	O	Output pin.
V-	4	I/O	Negative supply voltage pin.
V+	7	I/O	Positive supply voltage pin.

(1) Signal types: I = input, O = output, I/O = input or output.

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾ ⁽²⁾

		MIN	MAX	UNIT
V _S	Supply voltage (V ⁺ – V ⁻)		36	V
V _I	Differential input voltage		±10	V
V _{CM}	Common-mode voltage	(V ⁻) – 0.3	(V ⁺) + 0.3	V
I _{IN}	Input current		±10	mA
I _{SC}	Output current short to ground ⁽³⁾		Continuous	A
T _{stg}	Storage temperature	–65	150	°C
T _J	Junction temperature ⁽⁴⁾		150	°C
T _{SOLDER}	Infrared or convection reflow (20 seconds)		235	°C
	Wave soldering lead temp (10 seconds)		260	

- (1) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.
- (2) Stresses beyond those listed under *Absolute Maximum Rating* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Condition*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (3) Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C.
- (4) The maximum power dissipation is a function of T_{J(MAX)}, R_{θJA}, and T_A. The maximum allowable power dissipation at any ambient temperature is P_D = (T_{J(MAX)} – T_A)/R_{θJA}. All numbers apply for packages soldered directly into a PC board.

5.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V
		Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002 ⁽²⁾	±1500	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP155 states that 2500-V HBM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	TYP	MAX	UNIT
V _S	Supply voltage	5.5		34	V
T _A	Ambient temperature	–40		85	°C

5.4 Thermal Information

THERMAL METRIC ⁽¹⁾		LM6171			UNIT
		D (SOIC) A Version	D (SOIC) B Version	P (PDIP)	
		8 PINS	8 PINS	8 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	122.5	172	108	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	64.7	62.4	52.4	°C/W
R _{θJB}	Junction-to-board thermal resistance	65.9	55.7	51.9	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	17.6	16.5	6.8	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	65.1	55.1	51.1	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	°C/W

- (1) For information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

5.5 Electrical Characteristics: ± 15 V

at $T_J = 25^\circ\text{C}$, $V^+ = 15$ V, $V^- = -15$ V, $V_{CM} = 0$ V, and $R_L = 1$ k Ω (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN ⁽²⁾	TYP ⁽¹⁾	MAX ⁽²⁾	UNIT
V_{OS}	Input offset voltage	LM6171A	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	1.5	3	mV	
				5			
		LM6171B	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	1.5	6		
				8			
TCV_{OS}	Input offset voltage average drift			6		$\mu\text{V}/^\circ\text{C}$	
I_B	Input bias current			1	3	μA	
		$T_A = -40^\circ\text{C to } +85^\circ\text{C}$			4		
I_{OS}	Input offset current			0.03	2	μA	
		$T_A = -40^\circ\text{C to } +85^\circ\text{C}$			3		
R_{IN}	Input resistance	Common-mode		40		M Ω	
		Differential-mode		4.9			
R_O	Open-loop output resistance			14		Ω	
CMRR	Common-mode rejection ratio	LM6171A, $V_{CM} = \pm 10$ V	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	80	110	dB	
				75			
		LM6171B, $V_{CM} = \pm 10$ V	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	75	110		
				70			
PSRR	Power supply rejection ratio	LM6171A, $V_S = \pm 5$ V to ± 15 V	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	85	95	dB	
				80			
		LM6171B, $V_S = \pm 5$ V to ± 15 V	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	80	95		
				75			
V_{CM}	Input common-mode voltage	CMRR > 60 dB		± 13.5		V	
A_V	Large signal voltage gain ⁽³⁾	$R_L = 1$ k Ω , $V_{OUT} = \pm 5$ V	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	80	90	dB	
				70			
		$R_L = 100$ Ω , $V_{OUT} = \pm 5$ V	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	70	83		
				60			
V_O	Output swing	$R_L = 1$ k Ω , sourcing	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	12.5	13.3	V	
				12			
		$R_L = 1$ k Ω , sinking	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	-12.5	-13.3		
				-12			
		$R_L = 100$ Ω , sourcing	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	9	11.6		
				8.5			
		$R_L = 100$ Ω , sinking	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	-9	-10.5		
				-8.5			
	Continuous output current (open loop) ⁽⁴⁾	Sourcing, $R_L = 100$ Ω	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	90	116	mA	
				85			
		Sinking, $R_L = 100$ Ω	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	90	105		
				85			
	Continuous output current (in linear region)	Sourcing, $R_L = 100$ Ω		100		mA	
		Sinking, $R_L = 100$ Ω		80			
I_{SC}	Output short circuit current	Sourcing		135		mA	
		Sinking		135			
I_S	Supply current			2.5	4	mA	
		$T_A = -40^\circ\text{C to } +85^\circ\text{C}$			4.5		

5.5 Electrical Characteristics: ± 15 V (continued)

at $T_J = 25^\circ\text{C}$, $V^+ = 15$ V, $V^- = -15$ V, $V_{CM} = 0$ V, and $R_L = 1$ k Ω (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN ⁽²⁾	TYP ⁽¹⁾	MAX ⁽²⁾	UNIT
SR	Slew rate ⁽⁵⁾	$A_V = +2$, $V_{IN} = 13$ V _{PP}		3600			V/ μ s
		$A_V = +2$, $V_{IN} = 10$ V _{PP}		3000			
	Unity-gain bandwidth	LM6171A		76			MHz
		LM6171B		100			MHz
	-3-dB frequency	LM6171A	$A_V = +1$	200			MHz
			$A_V = +2$	75			
		LM6171B	$A_V = +1$	160			
			$A_V = +2$	62			
ϕ_m	Phase margin	LM6171A		58			Deg
		LM6171B		40			
t_s	Settling time (0.1%)	$A_V = -1$, $V_{OUT} = \pm 5$ V, $R_L = 500$ Ω	LM6171A	21			ns
			LM6171B	48			
t_p	Propagation delay	$A_V = -2$, $V_{IN} = \pm 5$ V, $R_L = 500$ Ω	LM6171A	4.1			ns
			LM6171B	6			
A_D	Differential gain ⁽⁶⁾			0.03			%
ϕ_D	Differential phase ⁽⁶⁾			0.5			$^\circ$
e_n	Input-referred voltage noise	$f = 10$ kHz		12			nV/ $\sqrt{\text{Hz}}$
i_n	Input-referred current noise	$f = 10$ kHz		1			pA/ $\sqrt{\text{Hz}}$

- (1) Typical values represent the most likely parametric norm
- (2) All limits are specified by testing or statistical analysis.
- (3) Large-signal voltage gain is the total output swing divided by the input signal required to produce that swing. For $V_S = \pm 15$ V, $V_{OUT} = \pm 5$ V. For $V_S = +5$ V, $V_{OUT} = \pm 1$ V.
- (4) The open-loop output current is the output swing with the 100- Ω load resistor divided by that resistor.
- (5) Slew rate is the average of the rising and falling slew rates.
- (6) Differential gain and phase are measured with $A_V = +2$, $V_{IN} = 1$ V_{PP} at 3.58 MHz and both input and output 75 Ω terminated.

5.6 Electrical Characteristics: ± 5 V

at $T_J = 25^\circ\text{C}$, $V^+ = 5$ V, $V^- = -5$ V, $V_{CM} = 0$ V, and $R_L = 1$ k Ω (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN ⁽²⁾	TYP ⁽¹⁾	MAX ⁽²⁾	UNIT
V_{OS}	Input offset voltage	LM6171A	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	1.2	3	mV	
				5			
		LM6171B	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	1.2	6		
				8			
TCV_{OS}	Input offset voltage average drift			4		$\mu\text{V}/^\circ\text{C}$	
I_B	Input bias current		$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	1	2.5	μA	
				3.5			
I_{OS}	Input offset current		$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	0.03	1.5	μA	
				2.2			
R_{IN}	Input resistance			40		M Ω	
				Differential-mode	4.9		
R_O	Open loop output resistance			14		Ω	
CMRR	Common-mode rejection ratio	LM6171A, $V_{CM} = \pm 2.5$ V	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	80	105	dB	
				75			
		LM6171B, $V_{CM} = \pm 2.5$ V	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	75	105		
				70			
PSRR	Power supply rejection ratio	LM6171A, $V_S = \pm 5$ V to ± 15 V	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	85	95	dB	
				80			
		LM6171B, $V_S = \pm 5$ V to ± 15 V	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	80	95		
				75			
V_{CM}	Input common-mode voltage	CMRR > 60 dB		LM6171A	± 3.2	V	
				LM6171B	± 3.7		
A_V	Large signal voltage gain ⁽³⁾	$R_L = 1$ k Ω , $V_{OUT} = \pm 1$ V	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	75	84	dB	
				65			
		$R_L = 100$ Ω , $V_{OUT} = \pm 1$ V	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	70	80		
				60			
V_O	Output swing	$R_L = 1$ k Ω , sourcing	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	3.2	3.5	V	
				3			
		$R_L = 1$ k Ω , sinking	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	-3.2	-3.4		
				-3			
		$R_L = 100$ Ω , sourcing	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	2.8	3.2		
				2.5			
		$R_L = 100$ Ω , sinking	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	-2.8	-3.0		
				-2.5			
	Continuous output current (open loop) ⁽⁴⁾	Sourcing, $R_L = 100$ Ω	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	28	32	mA	
				25			
		Sinking, $R_L = 100$ Ω	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	28	30		
				25			
I_{SC}	Output short circuit current				130	μA	
				Sinking	100		
I_S	Supply current		$T_A = -40^\circ\text{C to } +85^\circ\text{C}$	2.3	3	μA	
				3.5			
SR	Slew rate ⁽⁵⁾			$A_V = +2$, $V_{IN} = 3.5$ V _{PP}	750	V/ μs	
				$A_V = +2$, $V_{IN} = 2$ V _{PP}	450		

5.6 Electrical Characteristics: ± 5 V (continued)

at $T_J = 25^\circ\text{C}$, $V^+ = 5$ V, $V^- = -5$ V, $V_{CM} = 0$ V, and $R_L = 1$ k Ω (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN ⁽²⁾	TYP ⁽¹⁾	MAX ⁽²⁾	UNIT
	Unity-gain bandwidth	LM6171A		70			MHz
		LM6171B		70			
	-3-dB frequency	LM6171A	$A_V = +1$	190			MHz
			$A_V = +2$	75			
		LM6171B	$A_V = +1$	130			
			$A_V = +2$	45			
ϕ_m	Phase margin			57			Deg
t_s	Settling time (0.1%)	$A_V = -1$, $V_{OUT} = \pm 1$ V, $R_L = 500$ Ω	LM6171A	25			ns
			LM6171B	60			
t_p	Propagation delay	$A_V = -2$, $V_{IN} = \pm 1$ V, $R_L = 500$ Ω	LM6171A	4.5			ns
			LM6171B	8			
A_D	Differential gain ⁽⁶⁾			0.04			%
ϕ_D	Differential phase ⁽⁶⁾			0.7			°
e_n	Input-referred voltage noise	$f = 10$ kHz		11			nV/ $\sqrt{\text{Hz}}$
i_n	Input-referred current noise	$f = 10$ kHz		1			pA/ $\sqrt{\text{Hz}}$

- (1) Typical values represent the most likely parametric norm
- (2) All limits are specified by testing or statistical analysis.
- (3) Large-signal voltage gain is the total output swing divided by the input signal required to produce that swing. For $V_S = \pm 15$ V, $V_{OUT} = \pm 5$ V. For $V_S = +5$ V, $V_{OUT} = \pm 1$ V
- (4) The open-loop output current is the output swing with the 100- Ω load resistor divided by that resistor.
- (5) Slew rate is the average of the rising and falling slew rates.
- (6) Differential gain and phase are measured with $A_V = +2$, $V_{IN} = 1$ V_{PP} at 3.58 MHz and both input and output 75 Ω terminated.

5.7 Typical Characteristics: LM6171A Only

at $T_A = 25^\circ\text{C}$, and for LM6171A only (unless otherwise noted)

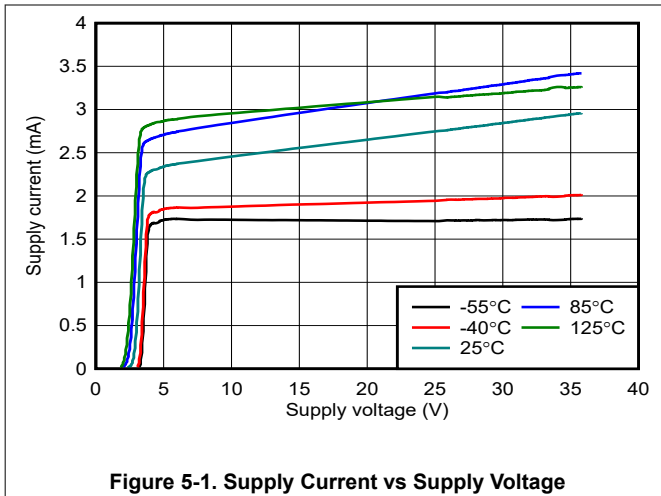


Figure 5-1. Supply Current vs Supply Voltage

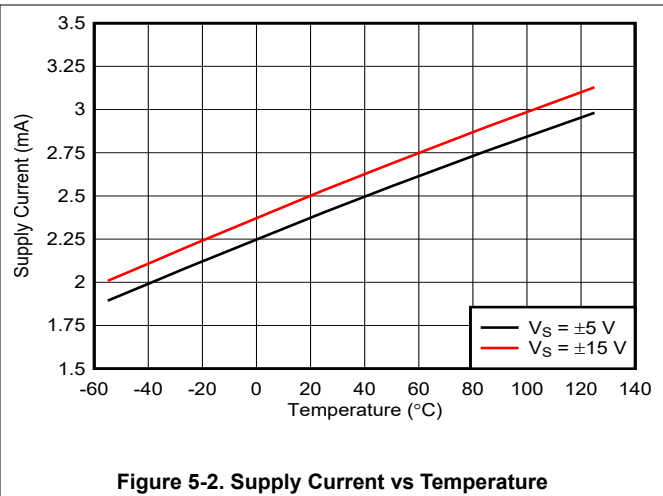


Figure 5-2. Supply Current vs Temperature

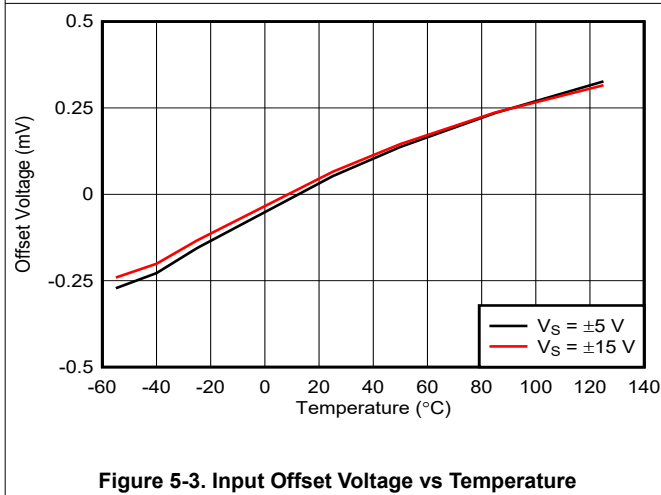


Figure 5-3. Input Offset Voltage vs Temperature

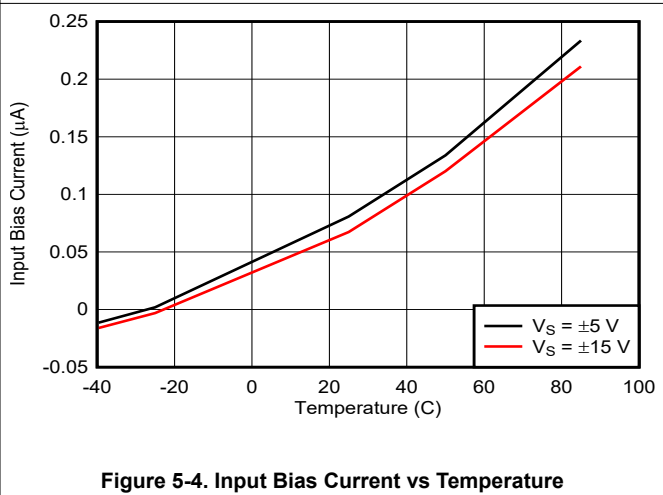


Figure 5-4. Input Bias Current vs Temperature

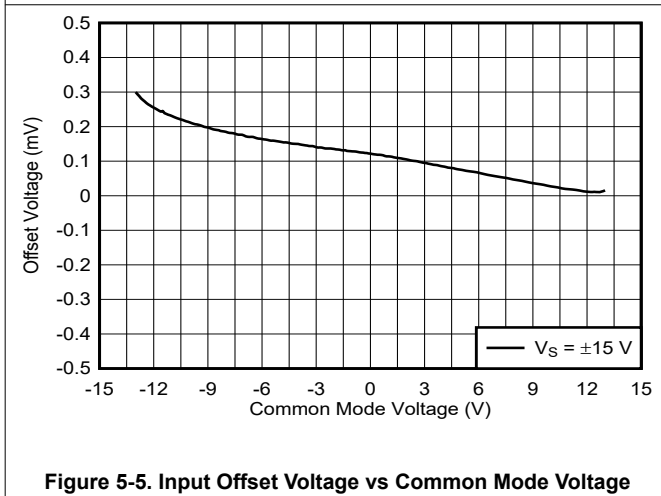


Figure 5-5. Input Offset Voltage vs Common Mode Voltage

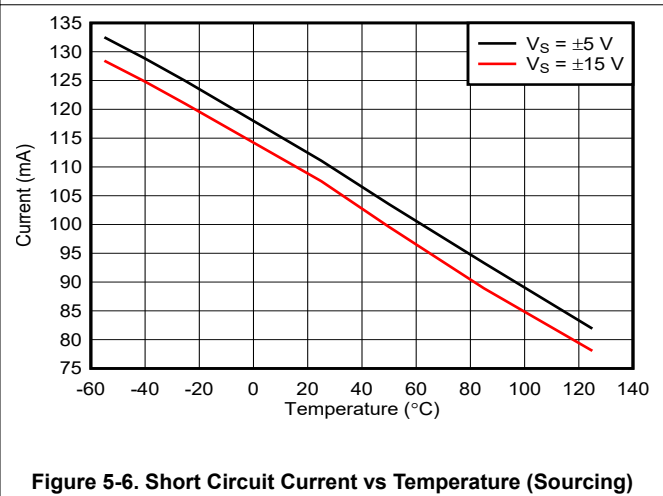


Figure 5-6. Short Circuit Current vs Temperature (Sourcing)

5.7 Typical Characteristics: LM6171A Only (continued)

at $T_A = 25^\circ\text{C}$, and for LM6171A only (unless otherwise noted)

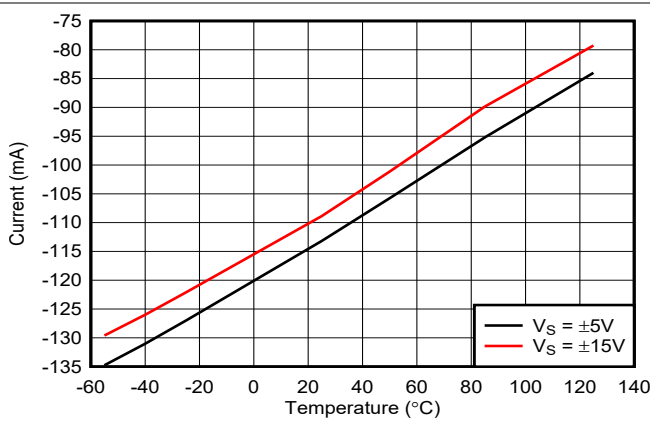


Figure 5-7. Short Circuit Current vs Temperature (Sinking)

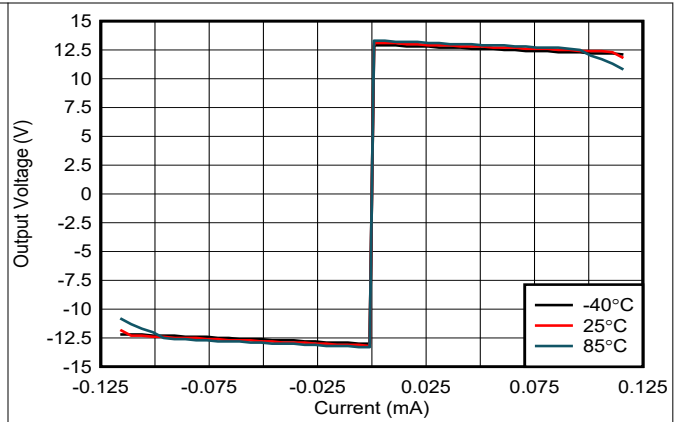


Figure 5-8. Output Voltage vs Output Current

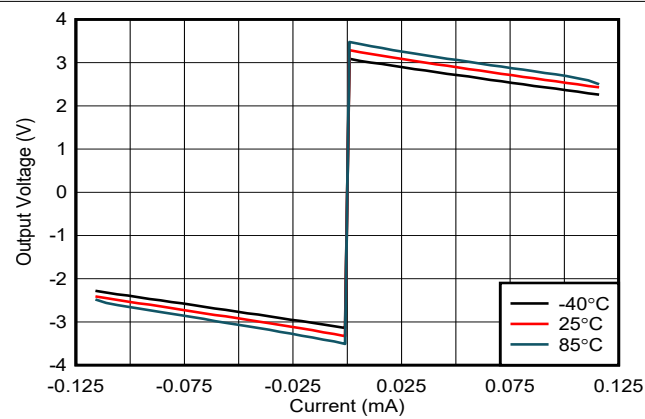


Figure 5-9. Output Voltage vs Output Current

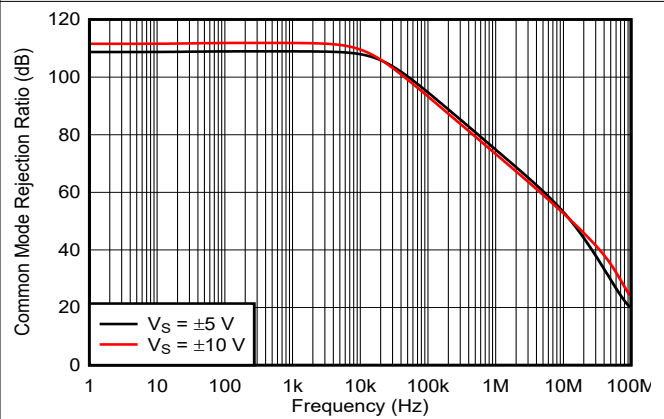


Figure 5-10. CMRR vs Frequency

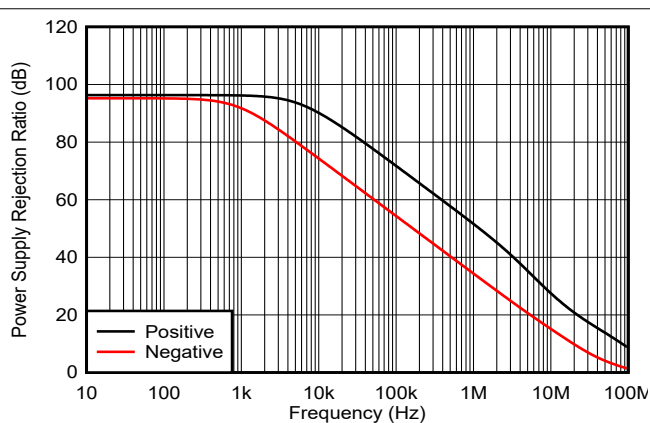


Figure 5-11. PSRR vs Frequency

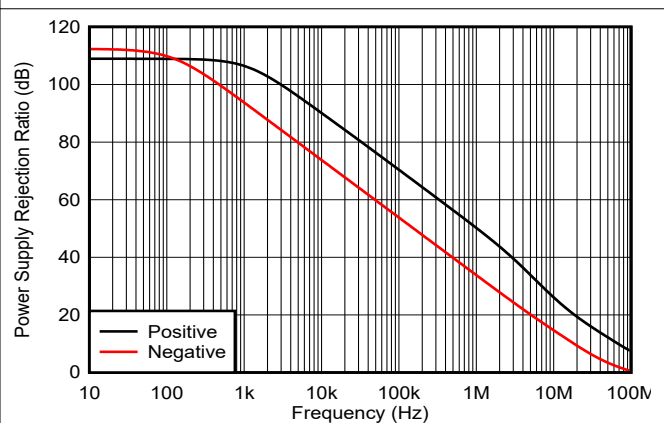


Figure 5-12. PSRR vs Frequency

5.7 Typical Characteristics: LM6171A Only (continued)

at $T_A = 25^\circ\text{C}$, and for LM6171A only (unless otherwise noted)

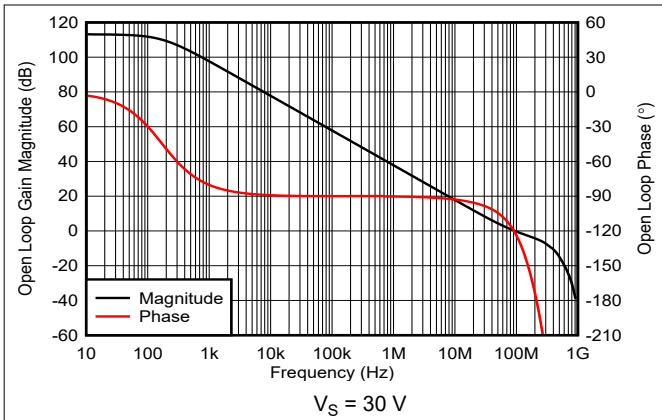


Figure 5-13. Open-Loop Frequency Response

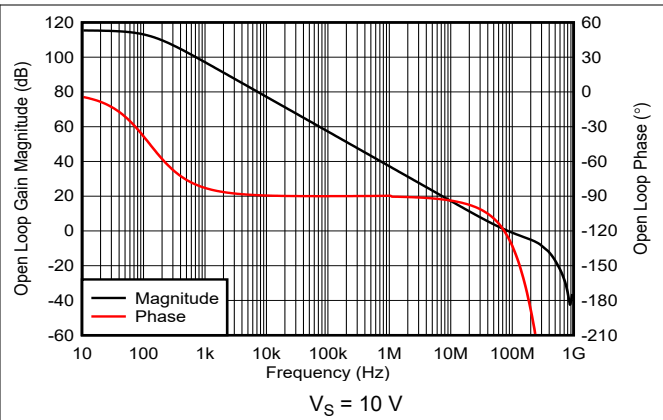


Figure 5-14. Open-Loop Frequency Response

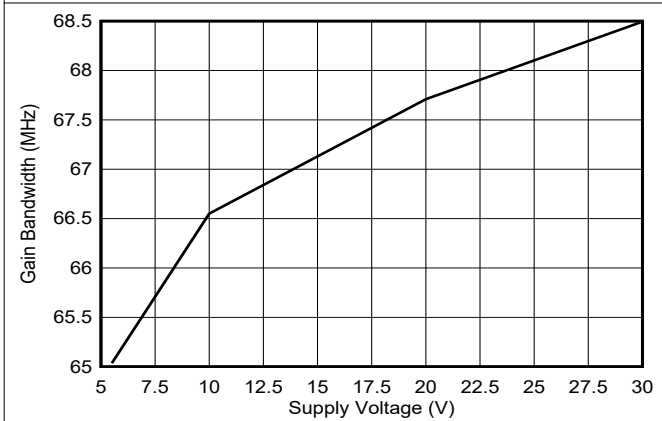


Figure 5-15. Gain Bandwidth Product vs Supply Voltage

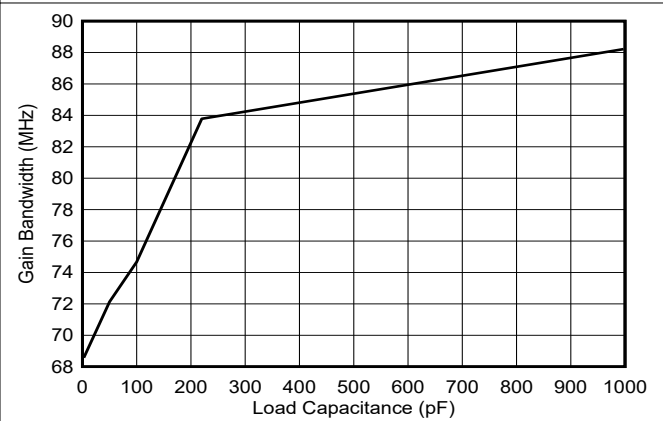


Figure 5-16. Gain Bandwidth Product vs Load Capacitance

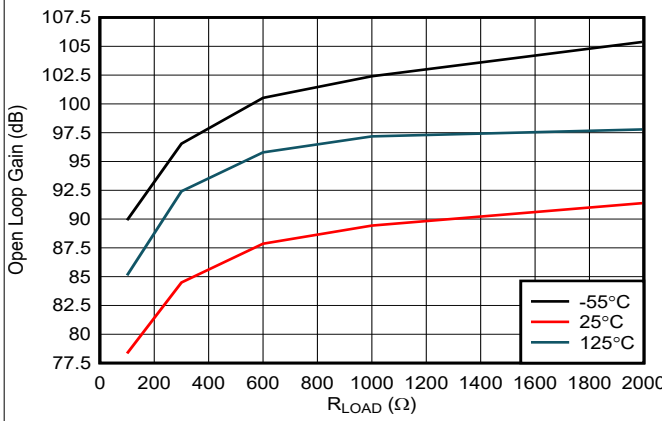


Figure 5-17. Large-Signal Voltage Gain vs Load

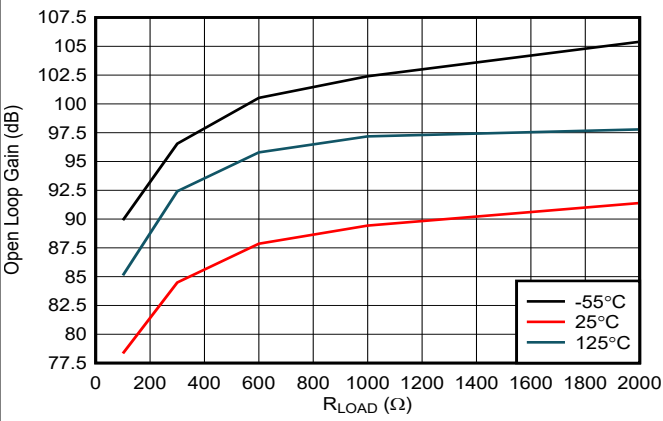


Figure 5-18. Large-Signal Voltage Gain vs Load

5.7 Typical Characteristics: LM6171A Only (continued)

at $T_A = 25^\circ\text{C}$, and for LM6171A only (unless otherwise noted)

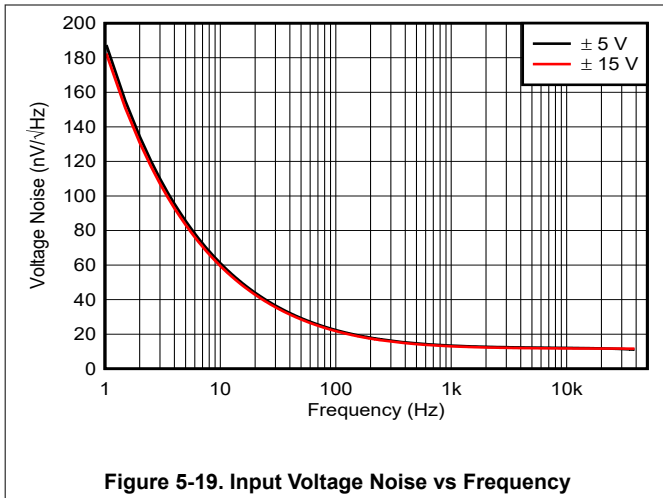


Figure 5-19. Input Voltage Noise vs Frequency

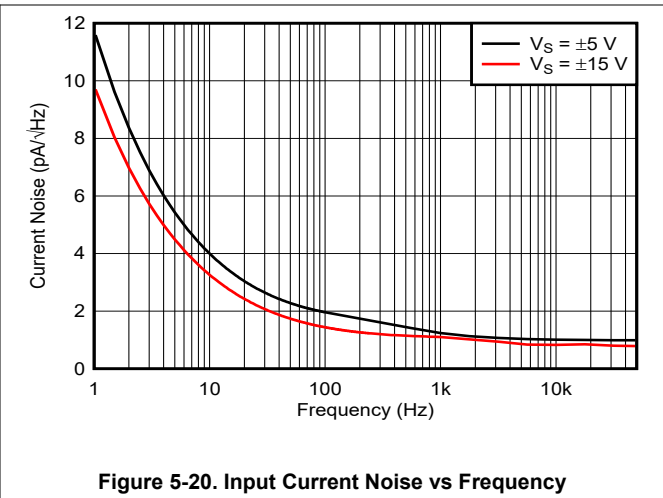


Figure 5-20. Input Current Noise vs Frequency

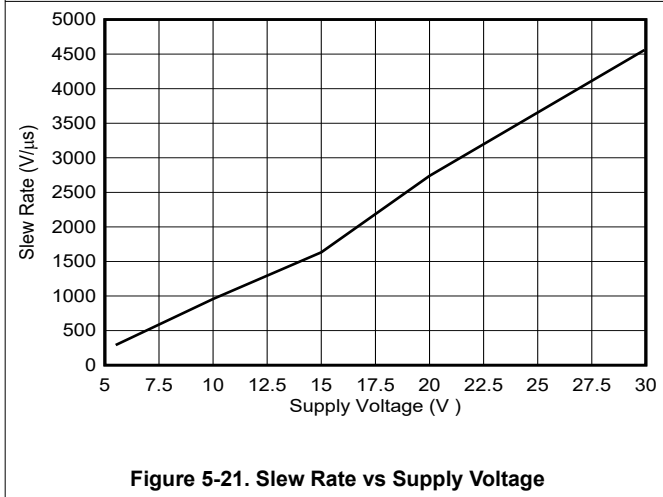


Figure 5-21. Slew Rate vs Supply Voltage

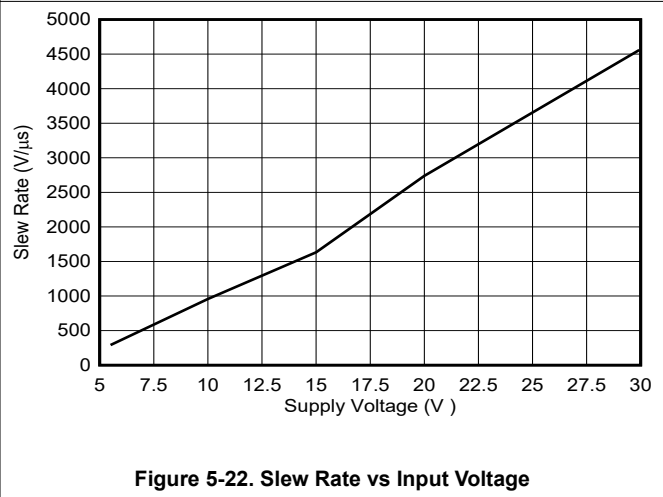


Figure 5-22. Slew Rate vs Input Voltage

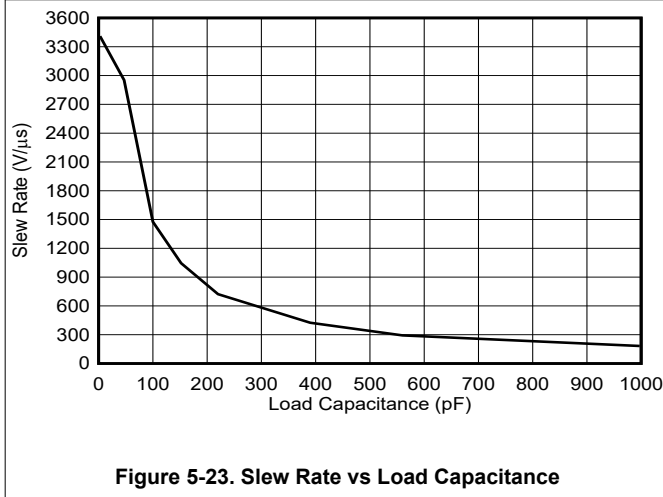


Figure 5-23. Slew Rate vs Load Capacitance

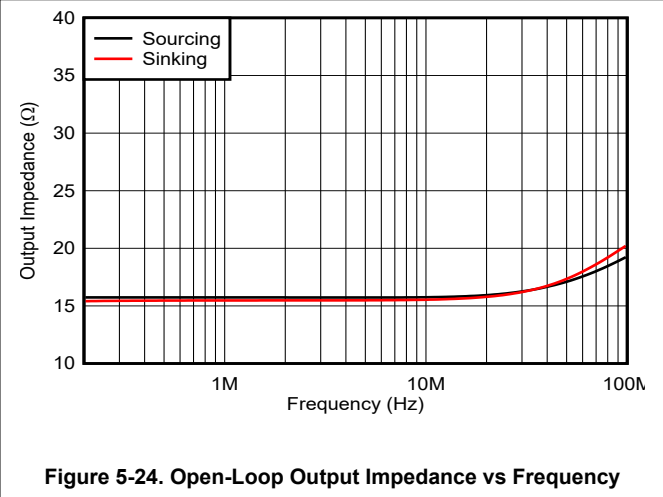


Figure 5-24. Open-Loop Output Impedance vs Frequency

5.7 Typical Characteristics: LM6171A Only (continued)

at $T_A = 25^\circ\text{C}$, and for LM6171A only (unless otherwise noted)

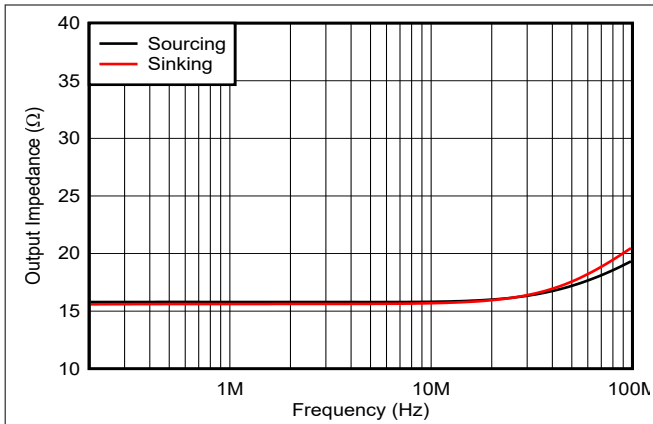
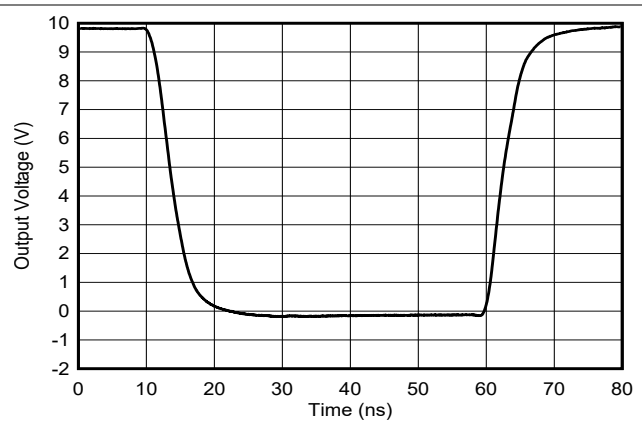
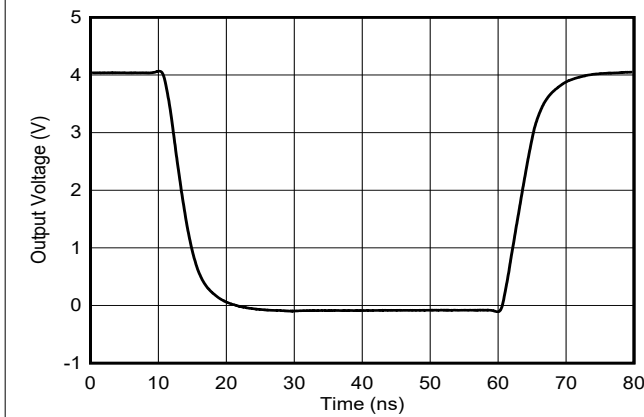


Figure 5-25. Open-Loop Output Impedance vs Frequency



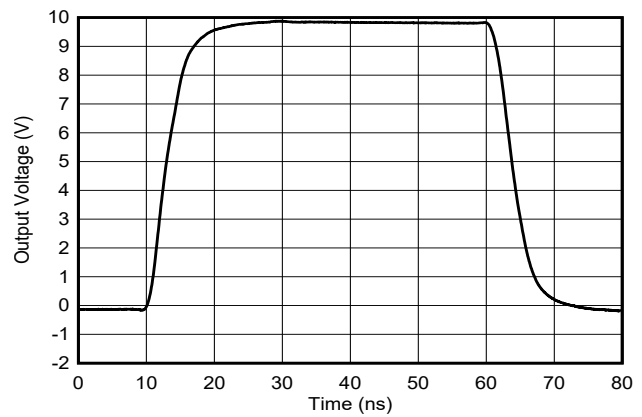
$A_V = -1, V_S = \pm 15\text{ V}$

Figure 5-26. Large-Signal Pulse Response



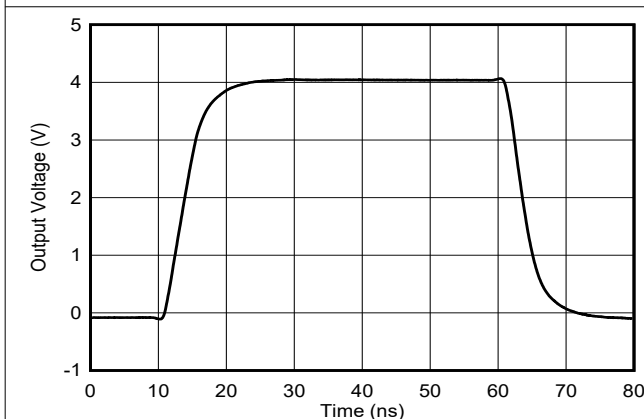
$A_V = -1, V_S = \pm 5\text{ V}$

Figure 5-27. Large-Signal Pulse Response



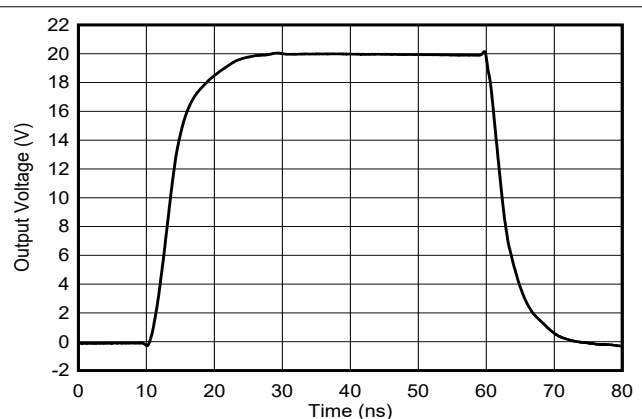
$A_V = 1, V_S = \pm 15\text{ V}$

Figure 5-28. Large-Signal Pulse Response



$A_V = 1, V_S = \pm 5\text{ V}$

Figure 5-29. Large-Signal Pulse Response

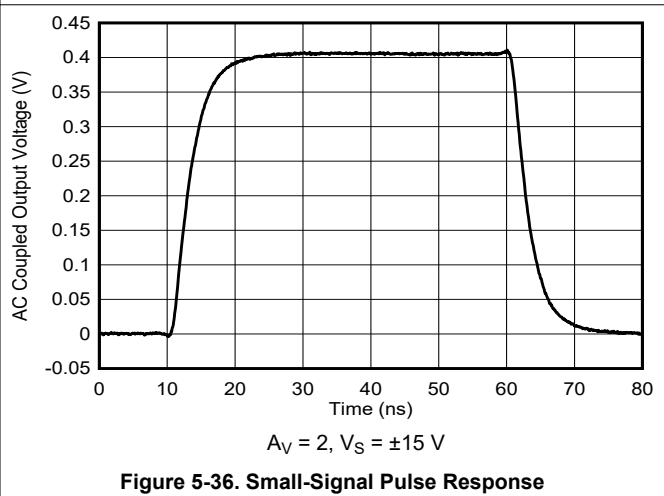
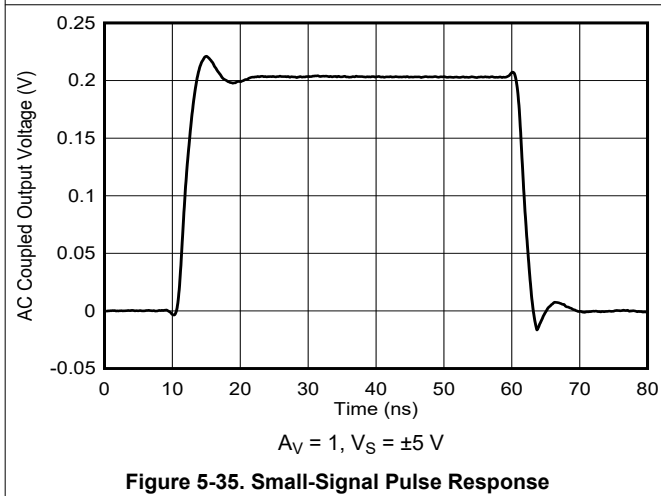
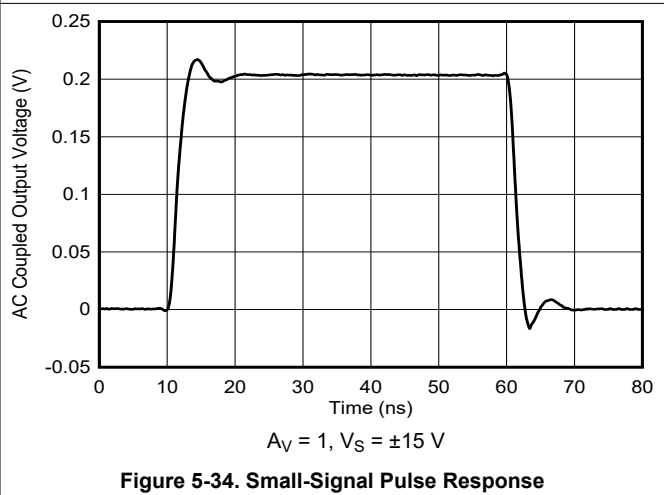
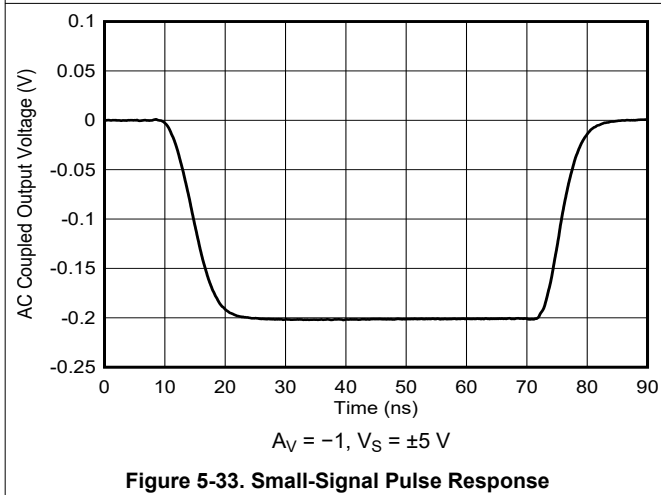
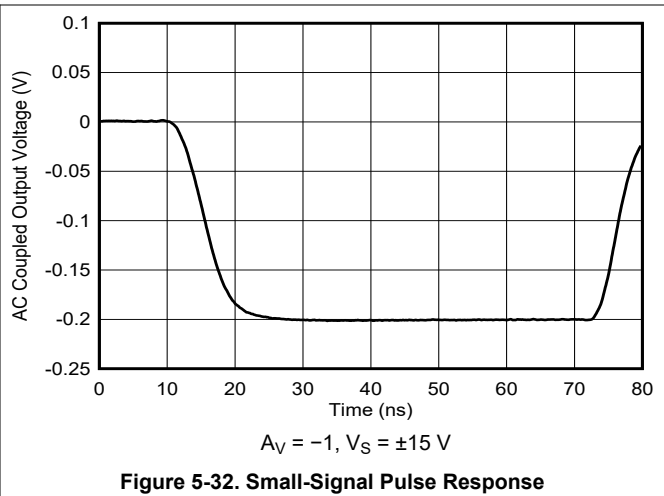
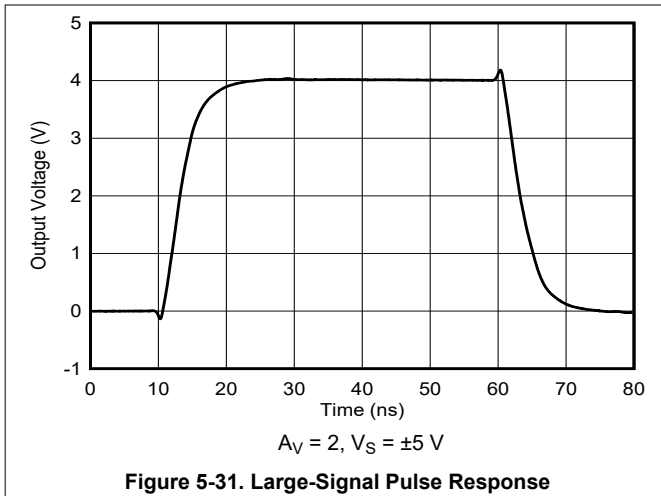


$A_V = 2, V_S = \pm 15\text{ V}$

Figure 5-30. Large-Signal Pulse Response

5.7 Typical Characteristics: LM6171A Only (continued)

at $T_A = 25^\circ\text{C}$, and for LM6171A only (unless otherwise noted)



5.7 Typical Characteristics: LM6171A Only (continued)

at $T_A = 25^\circ\text{C}$, and for LM6171A only (unless otherwise noted)

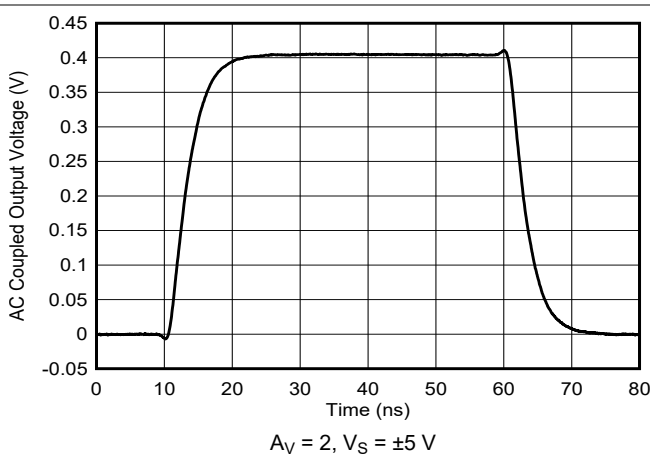


Figure 5-37. Small-Signal Pulse Response

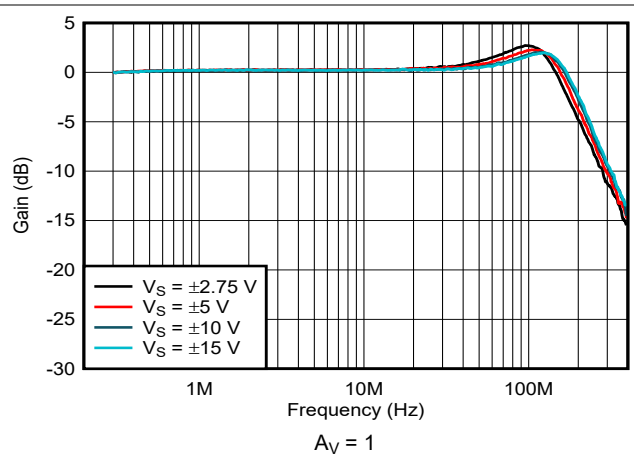


Figure 5-38. Closed-Loop Frequency Response vs Supply Voltage

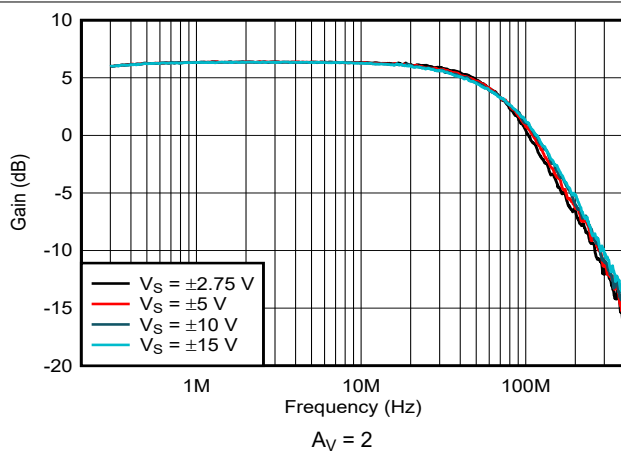


Figure 5-39. Closed-Loop Frequency Response vs Supply Voltage

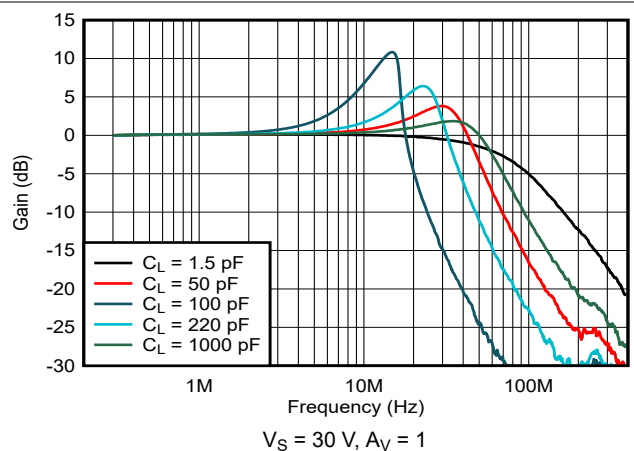


Figure 5-40. Closed-Loop Frequency Response vs Capacitive Load

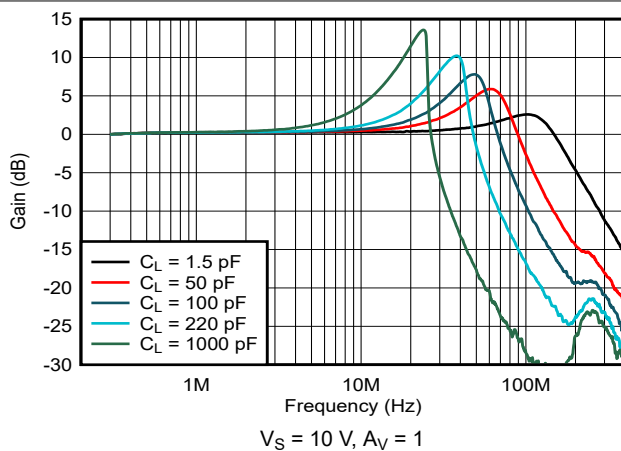


Figure 5-41. Closed Loop Frequency Response vs Capacitive Load

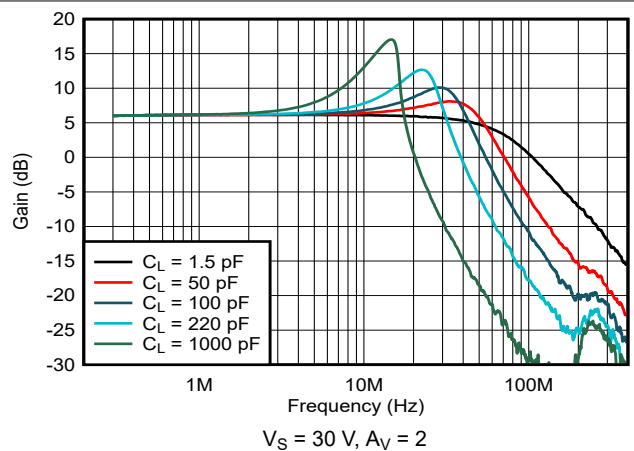


Figure 5-42. Closed-Loop Frequency Response vs Capacitive Load

5.7 Typical Characteristics: LM6171A Only (continued)

at $T_A = 25^\circ\text{C}$, and for LM6171A only (unless otherwise noted)

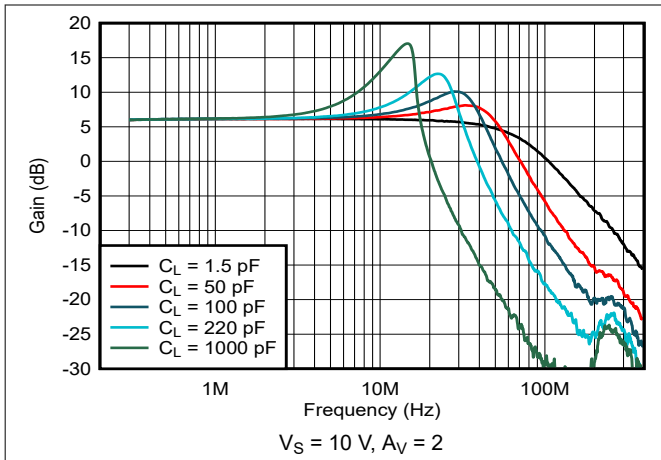


Figure 5-43. Closed-Loop Frequency Response vs Capacitive Load

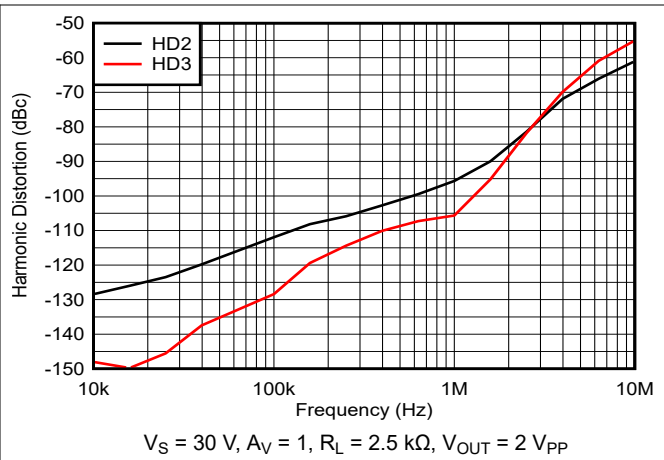


Figure 5-44. Harmonic Distortion vs Frequency

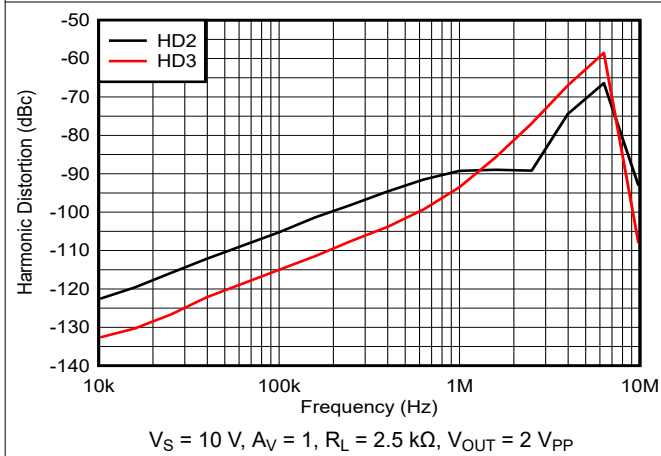


Figure 5-45. Total Harmonic Distortion vs Frequency

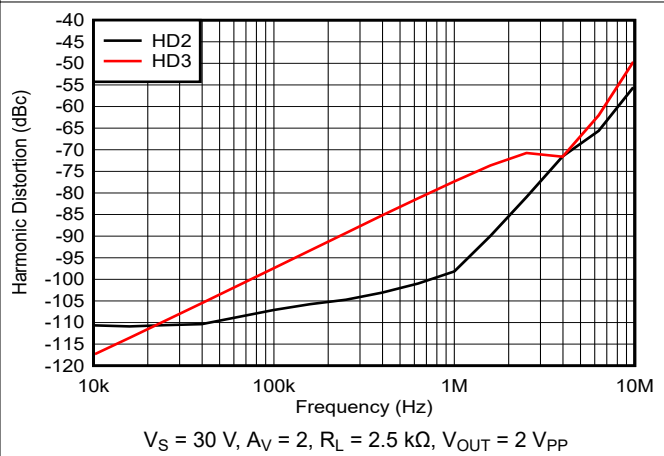


Figure 5-46. Total Harmonic Distortion vs Frequency

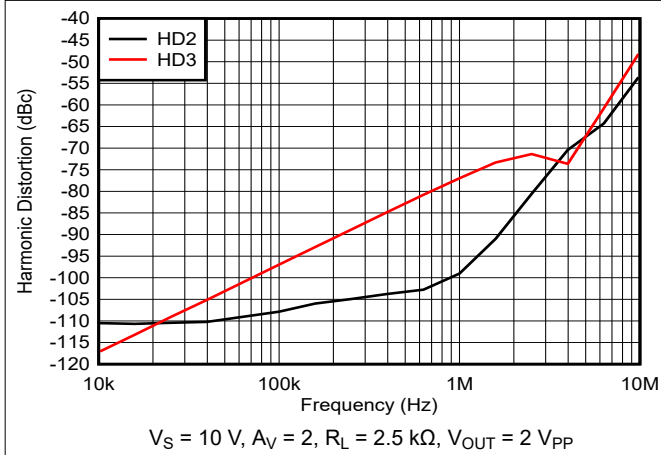


Figure 5-47. Total Harmonic Distortion vs Frequency

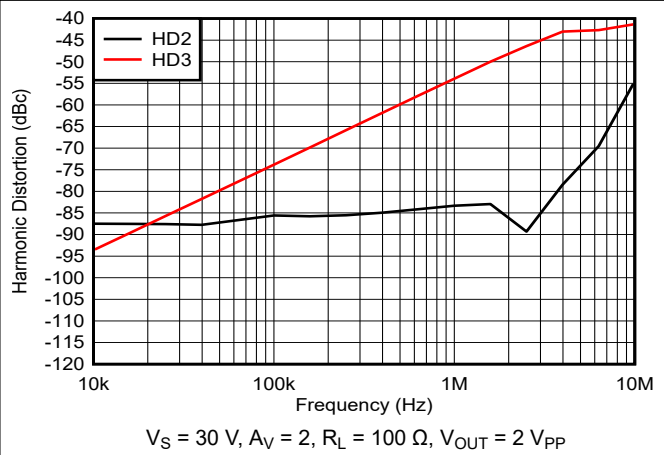
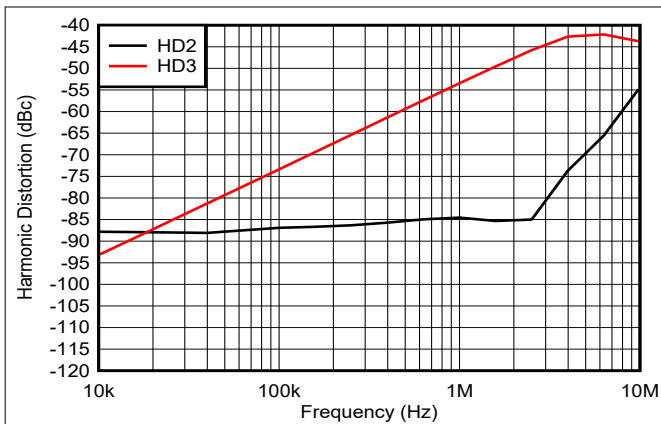


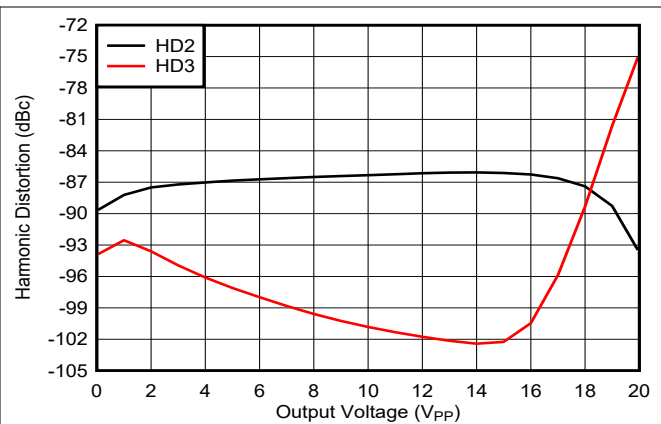
Figure 5-48. Harmonic Distortion vs Frequency

5.7 Typical Characteristics: LM6171A Only (continued)

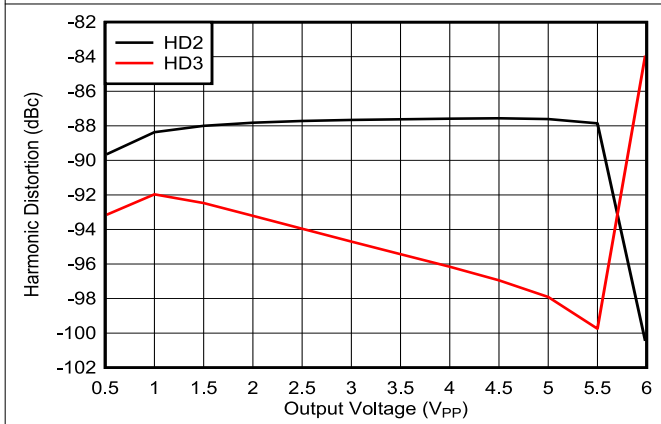
at $T_A = 25^\circ\text{C}$, and for LM6171A only (unless otherwise noted)



$V_S = 10\text{ V}$, $A_V = 2$, $R_L = 100\ \Omega$, $V_{OUT} = 2\ V_{PP}$
Figure 5-49. Harmonic Distortion vs Frequency



$V_S = 30\text{ V}$, $A_V = 2$, $R_L = 100\ \Omega$, $V_{OUT} = 2\ V_{PP}$, $f = 10\text{ kHz}$
Figure 5-50. Harmonic Distortion vs Output Voltage Peak to Peak



$V_S = 10\text{ V}$, $A_V = 2$, $R_L = 100\ \Omega$, $V_{OUT} = 2\ V_{PP}$, $f = 10\text{ kHz}$
Figure 5-51. Harmonic Distortion vs Output Voltage Peak to Peak

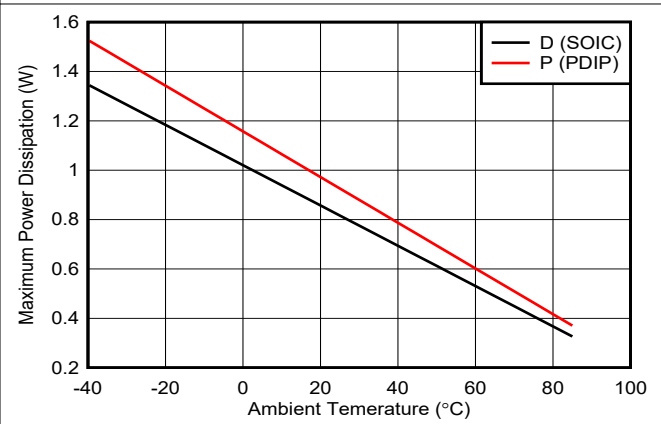


Figure 5-52. Total Power Dissipation vs Ambient Temperature

5.8 Typical Characteristics

at $T_A = 25^\circ\text{C}$ (unless otherwise noted)

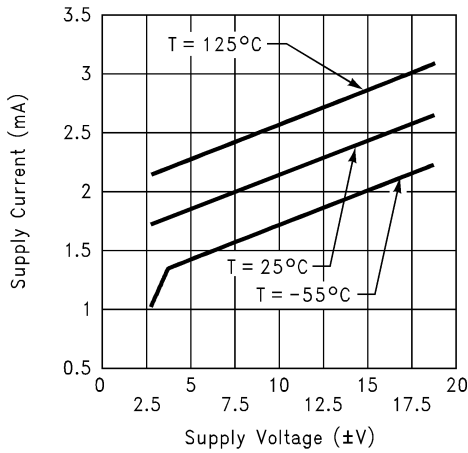


Figure 5-53. Supply Current vs Supply Voltage

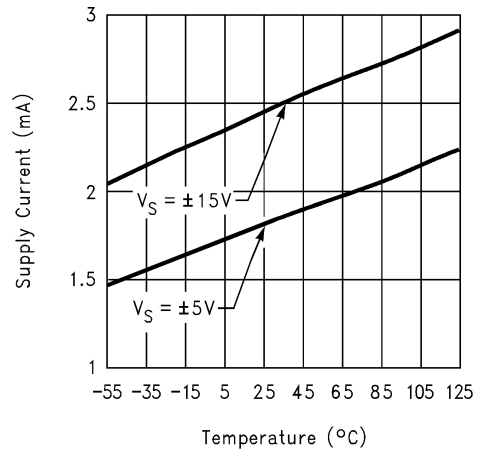


Figure 5-54. Supply Current vs Temperature

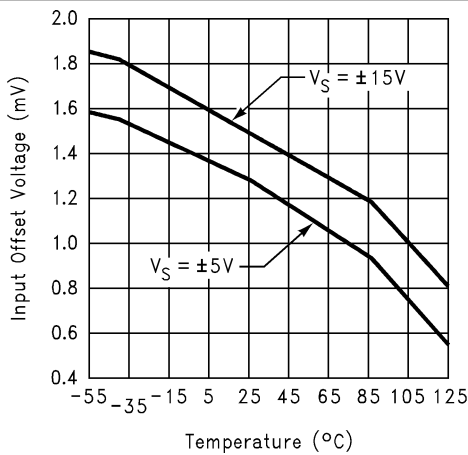


Figure 5-55. Input Offset Voltage vs Temperature

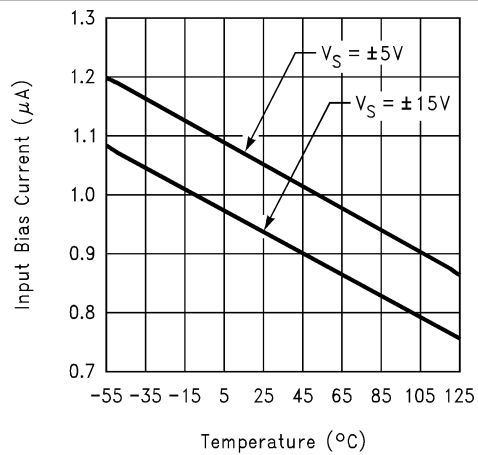


Figure 5-56. Input Bias Current vs Temperature

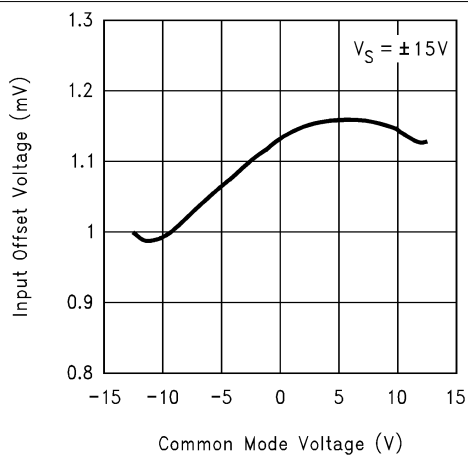


Figure 5-57. Input Offset Voltage vs Common Mode Voltage

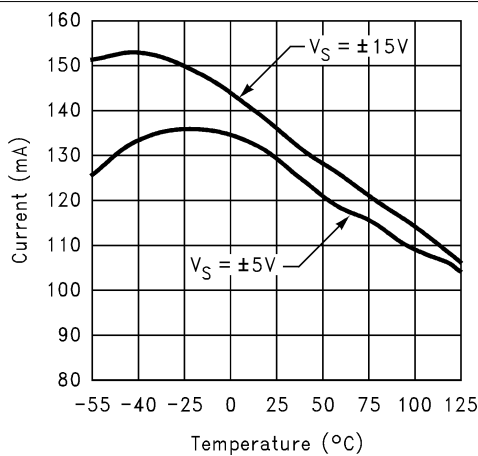


Figure 5-58. Short Circuit Current vs Temperature (Sourcing)

5.8 Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$ (unless otherwise noted)

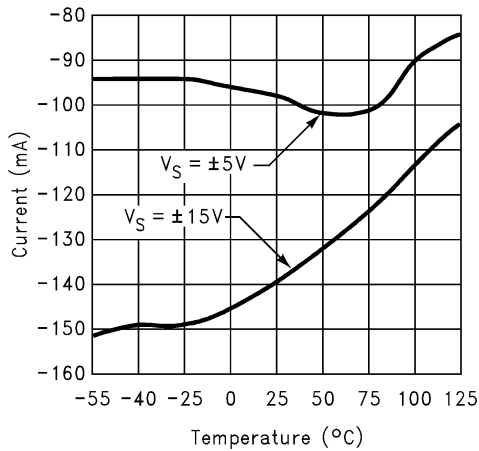


Figure 5-59. Short Circuit Current vs Temperature (Sinking)

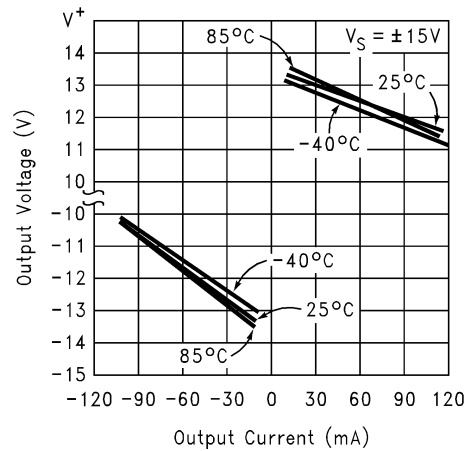


Figure 5-60. Output Voltage vs Output Current

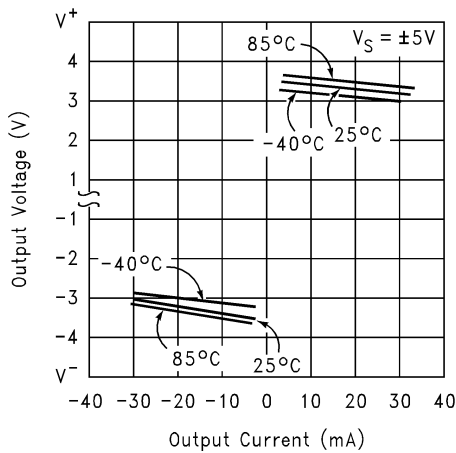


Figure 5-61. Output Voltage vs Output Current

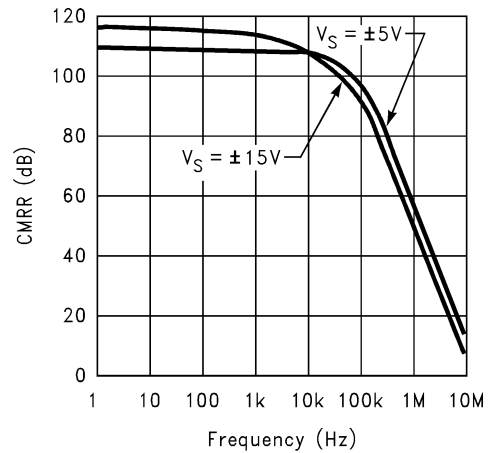


Figure 5-62. CMRR vs Frequency

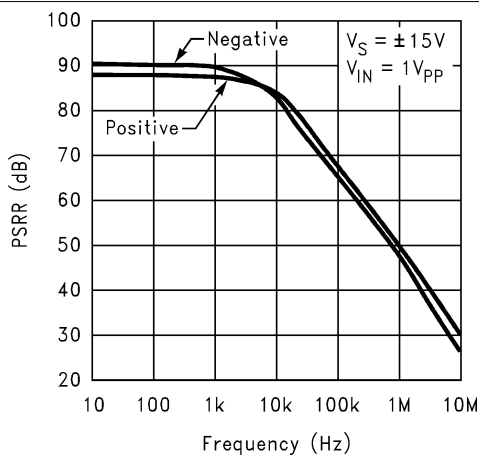


Figure 5-63. PSRR vs Frequency

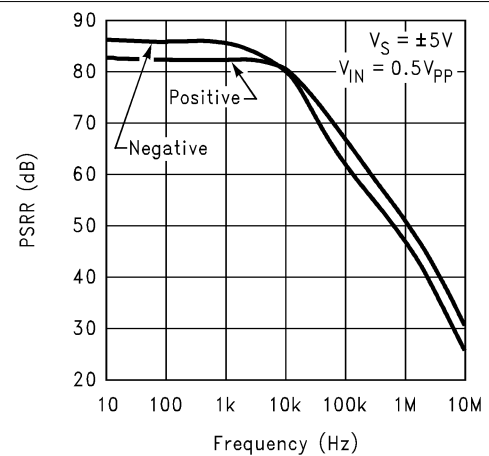


Figure 5-64. PSRR vs Frequency

5.8 Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$ (unless otherwise noted)

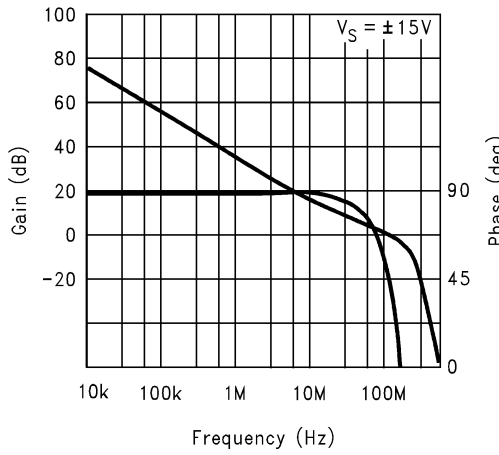


Figure 5-65. Open-Loop Frequency Response

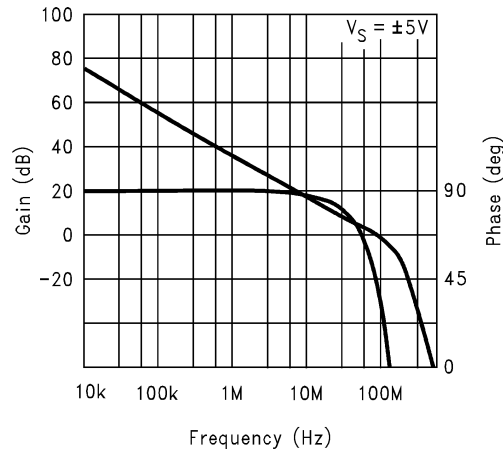


Figure 5-66. Open-Loop Frequency Response

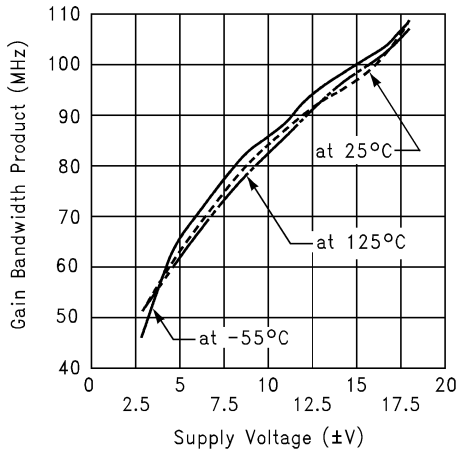


Figure 5-67. Gain Bandwidth Product vs Supply Voltage

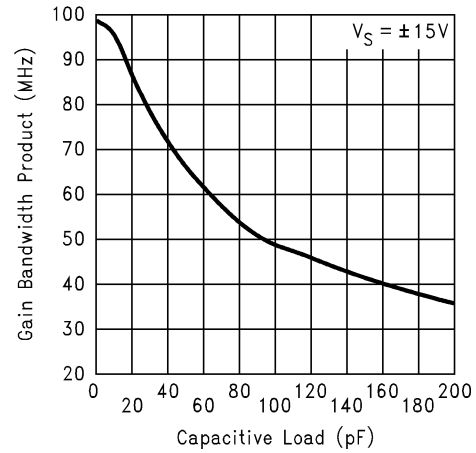


Figure 5-68. Gain Bandwidth Product vs Load Capacitance

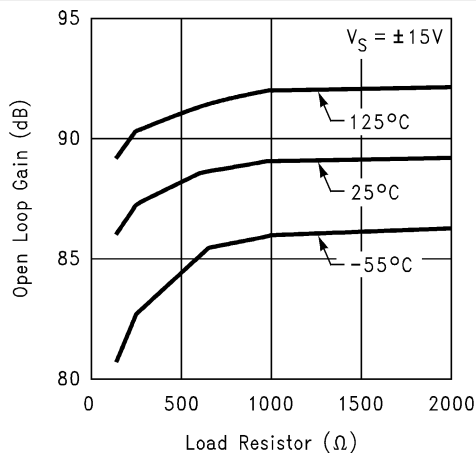


Figure 5-69. Large-Signal Voltage Gain vs Load

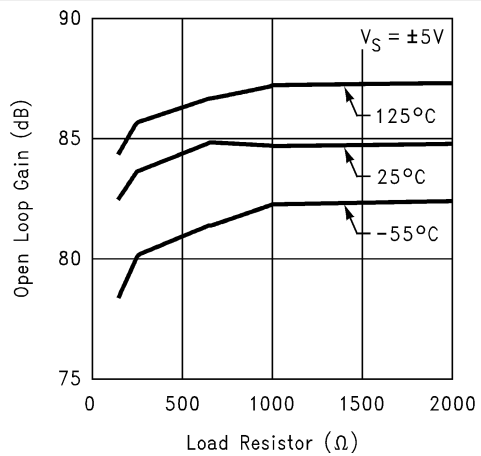


Figure 5-70. Large-Signal Voltage Gain vs Load

5.8 Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$ (unless otherwise noted)

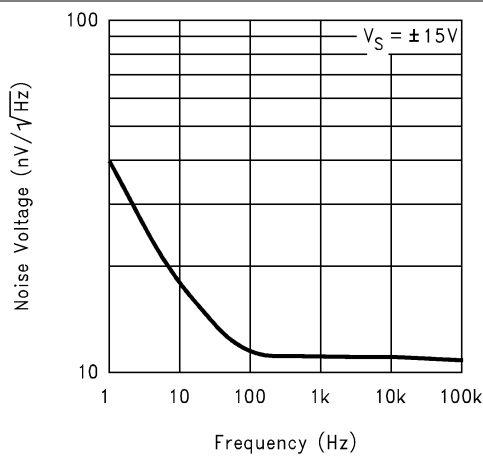


Figure 5-71. Input Voltage Noise vs Frequency

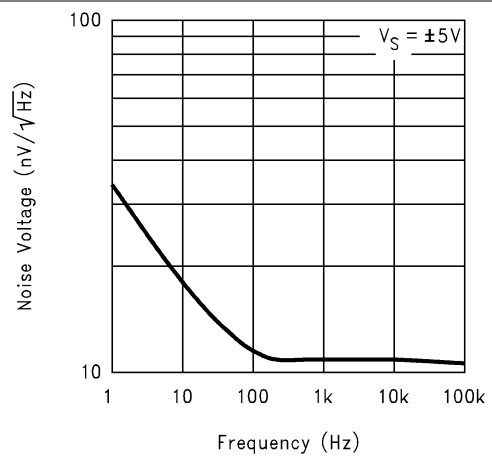


Figure 5-72. Input Voltage Noise vs Frequency

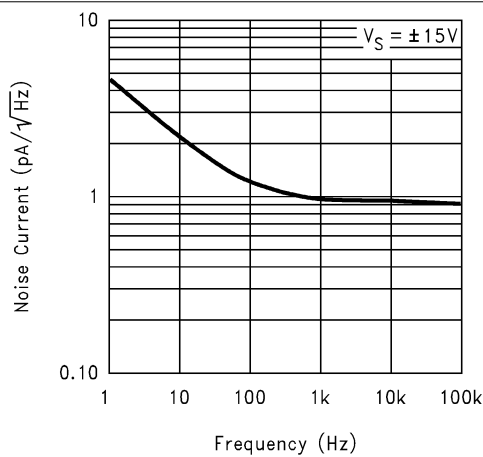


Figure 5-73. Input Current Noise vs Frequency

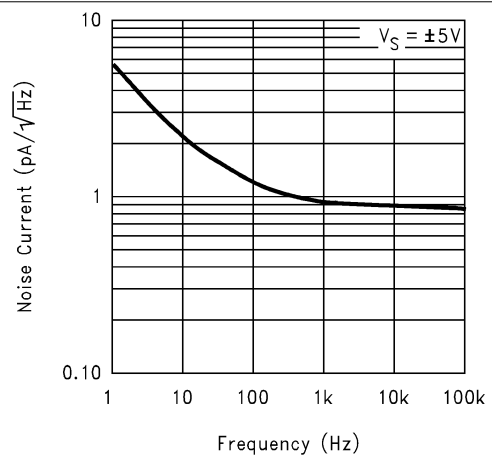


Figure 5-74. Input Current Noise vs Frequency

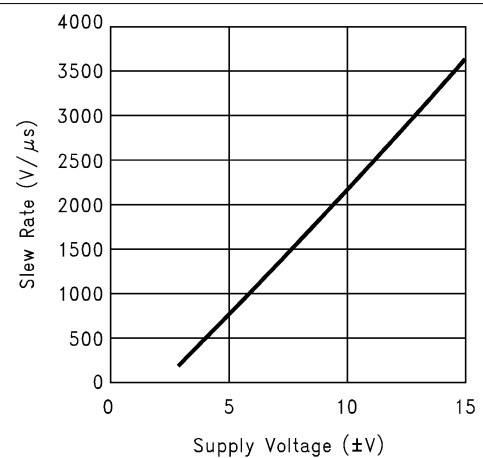


Figure 5-75. Slew Rate vs Supply Voltage

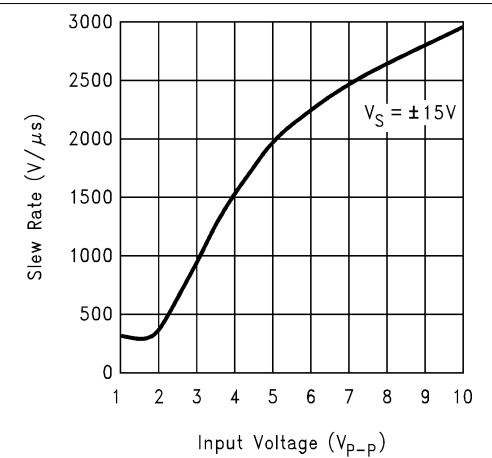


Figure 5-76. Slew Rate vs Input Voltage

5.8 Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$ (unless otherwise noted)

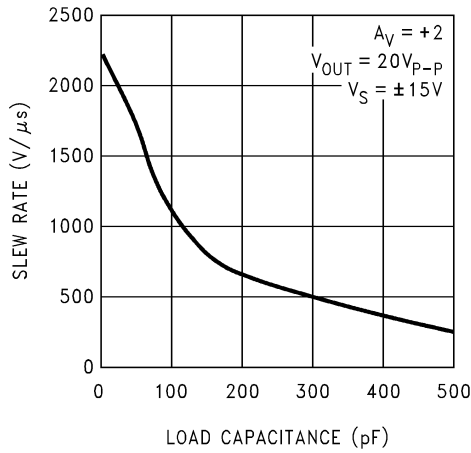


Figure 5-77. Slew Rate vs Load Capacitance

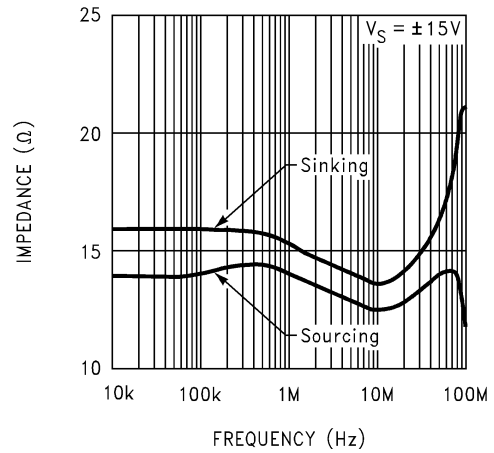


Figure 5-78. Open-Loop Output Impedance vs Frequency

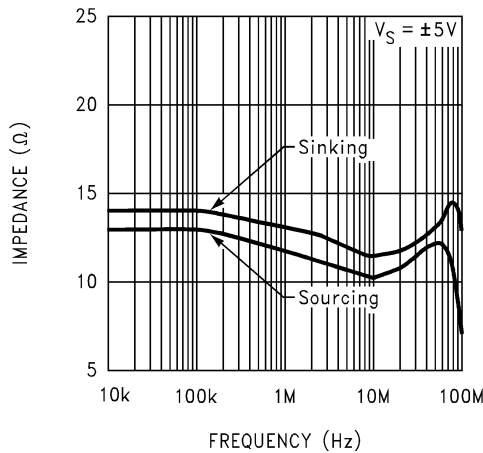


Figure 5-79. Open-Loop Output Impedance vs Frequency

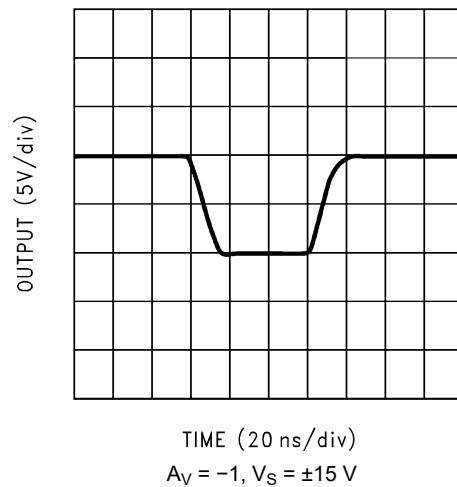


Figure 5-80. Large-Signal Pulse Response

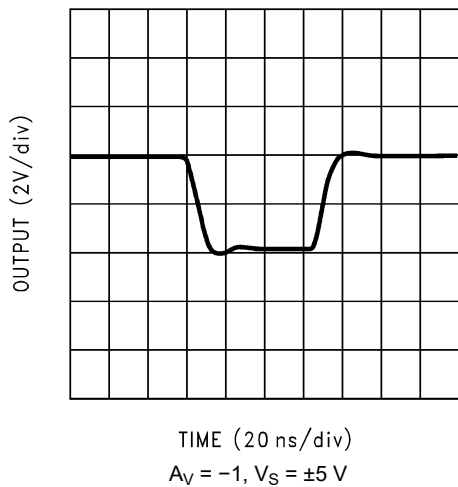


Figure 5-81. Large-Signal Pulse Response

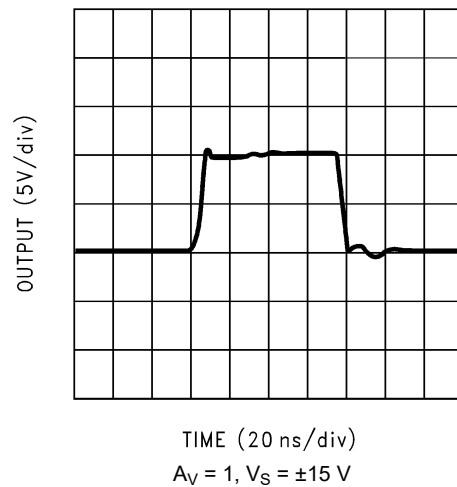
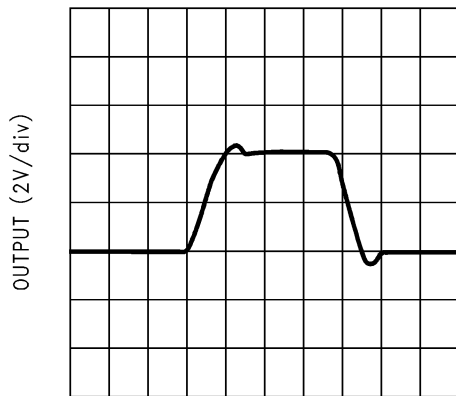


Figure 5-82. Large-Signal Pulse Response

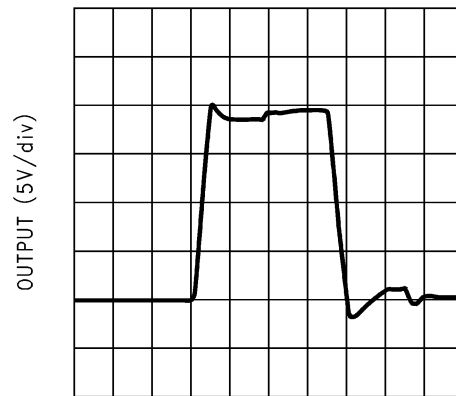
5.8 Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$ (unless otherwise noted)



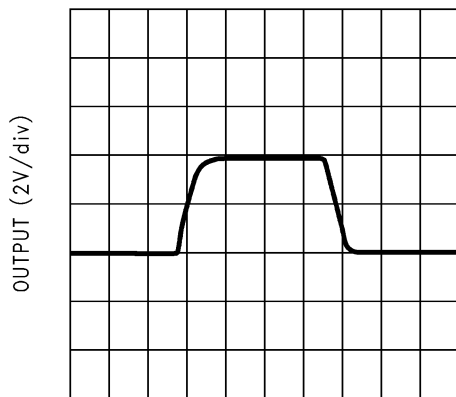
TIME (2 ns/div)
 $A_V = 1, V_S = \pm 5\text{ V}$

Figure 5-83. Large-Signal Pulse Response



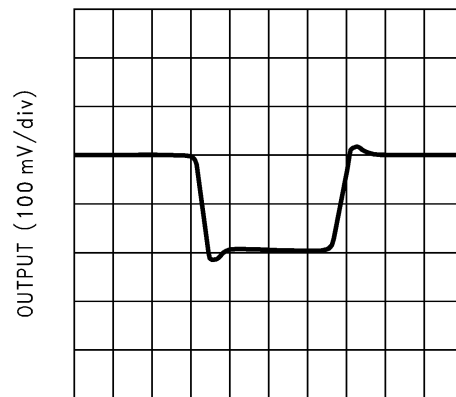
TIME (20 ns/div)
 $A_V = 2, V_S = \pm 15\text{ V}$

Figure 5-84. Large-Signal Pulse Response



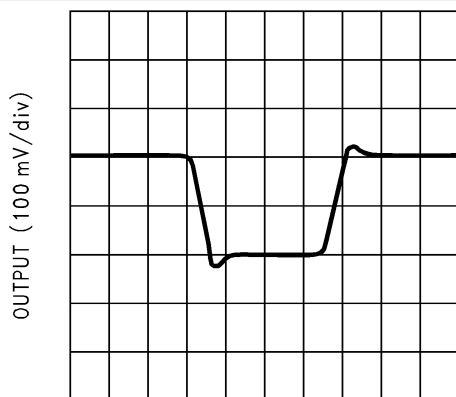
TIME (20 ns/div)
 $A_V = 2, V_S = \pm 5\text{ V}$

Figure 5-85. Large-Signal Pulse Response



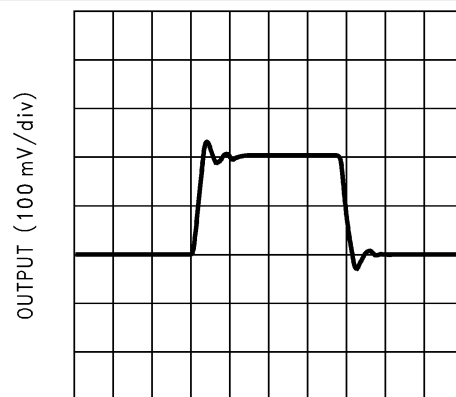
TIME (20 ns/div)
 $A_V = -1, V_S = \pm 15\text{ V}$

Figure 5-86. Small-Signal Pulse Response



TIME (20 ns/div)
 $A_V = -1, V_S = \pm 5\text{ V}$

Figure 5-87. Small-Signal Pulse Response



TIME (20 ns/div)
 $A_V = 1, V_S = \pm 15\text{ V}$

Figure 5-88. Small-Signal Pulse Response

5.8 Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$ (unless otherwise noted)

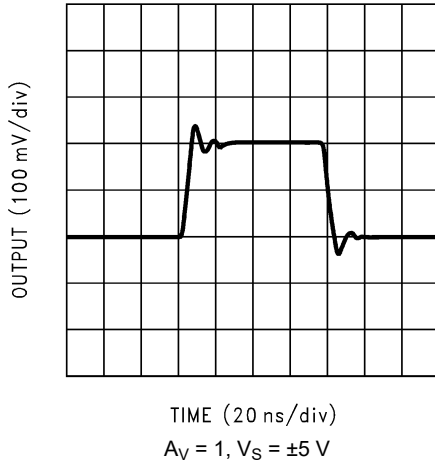


Figure 5-89. Small-Signal Pulse Response

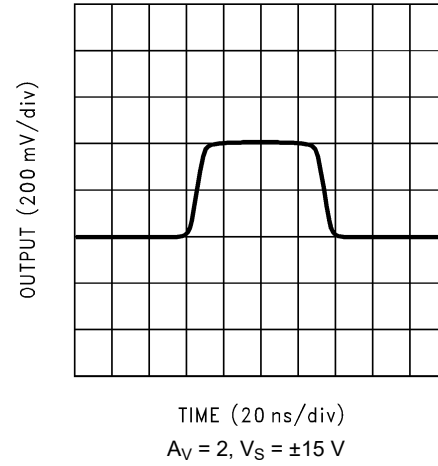


Figure 5-90. Small-Signal Pulse Response

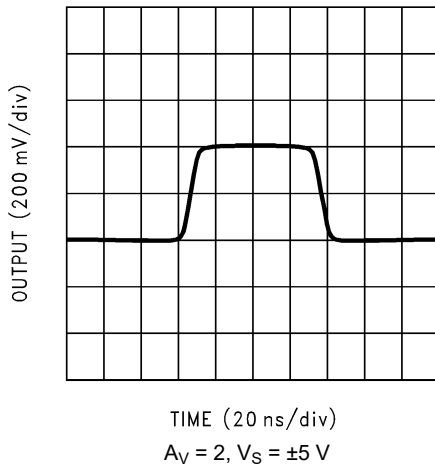


Figure 5-91. Small-Signal Pulse Response

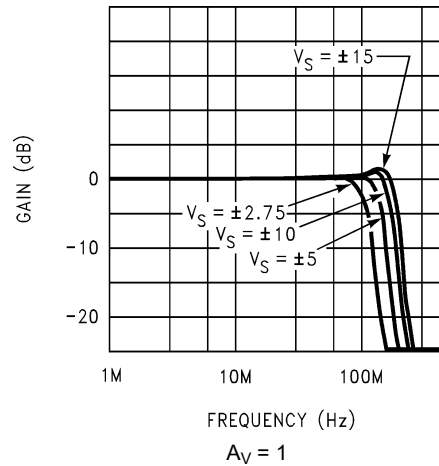


Figure 5-92. Closed-Loop Frequency Response vs Supply Voltage

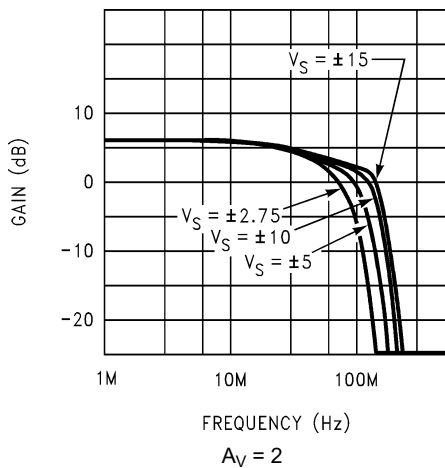


Figure 5-93. Closed-Loop Frequency Response vs Supply Voltage

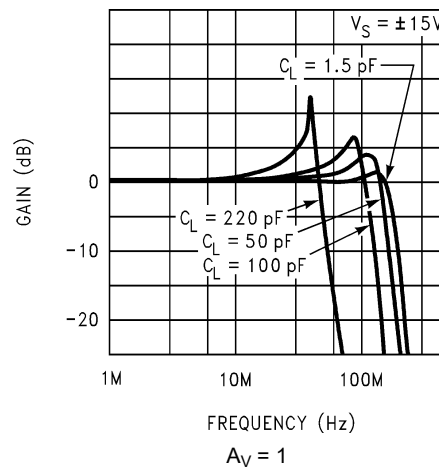


Figure 5-94. Closed-Loop Frequency Response vs Capacitive Load

5.8 Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$ (unless otherwise noted)

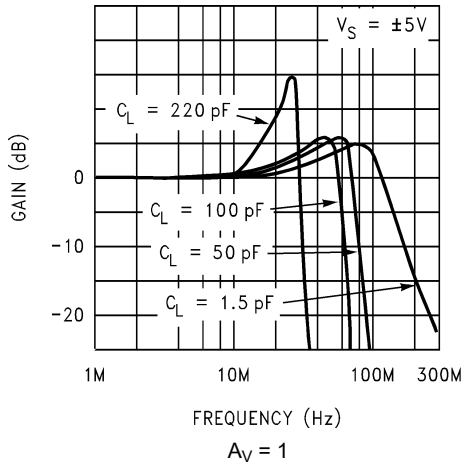


Figure 5-95. Closed Loop Frequency Response vs Capacitive Load

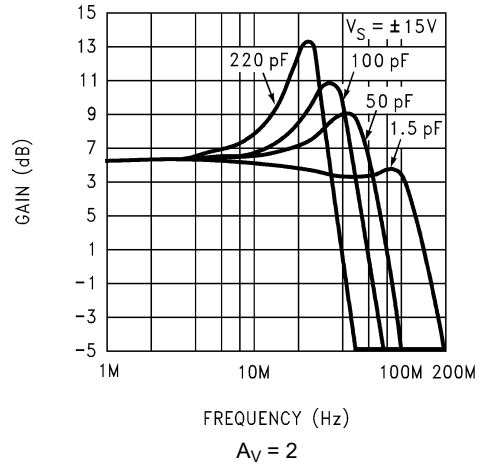


Figure 5-96. Closed-Loop Frequency Response vs Capacitive Load

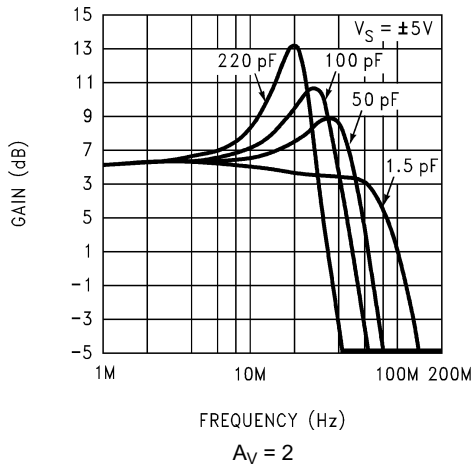


Figure 5-97. Closed-Loop Frequency Response vs Capacitive Load

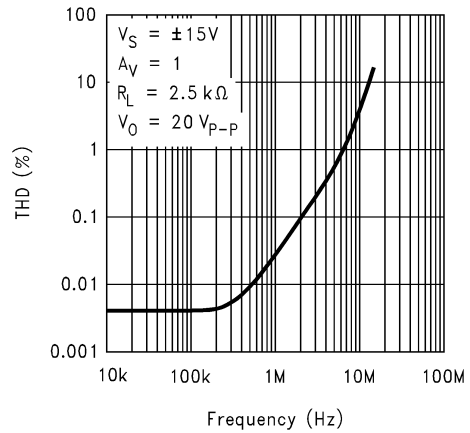


Figure 5-98. Total Harmonic Distortion vs Frequency

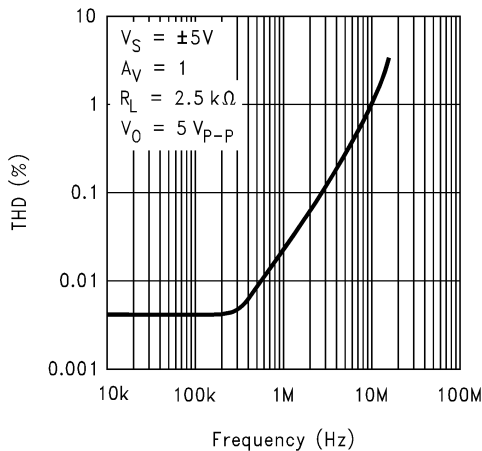


Figure 5-99. Total Harmonic Distortion vs Frequency

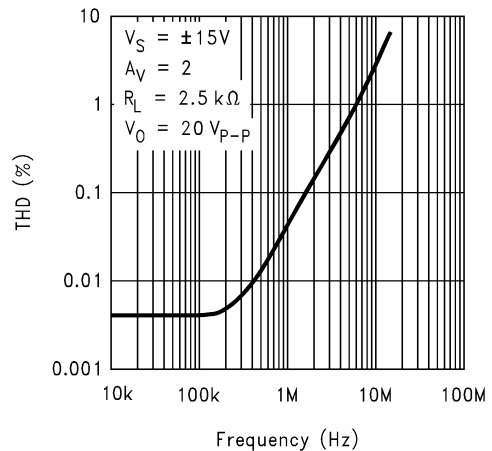


Figure 5-100. Total Harmonic Distortion vs Frequency

5.8 Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$ (unless otherwise noted)

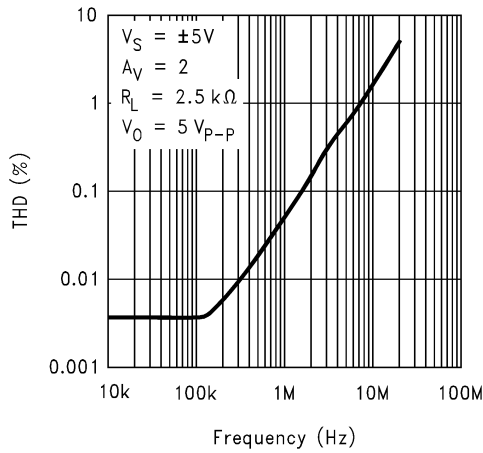


Figure 5-101. Total Harmonic Distortion vs Frequency

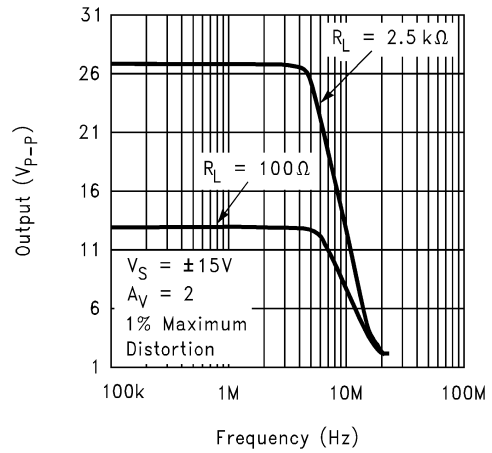


Figure 5-102. Undistorted Output Swing vs Frequency

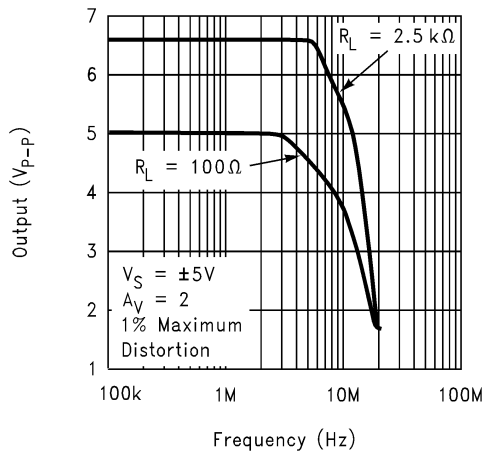


Figure 5-103. Undistorted Output Swing vs Frequency

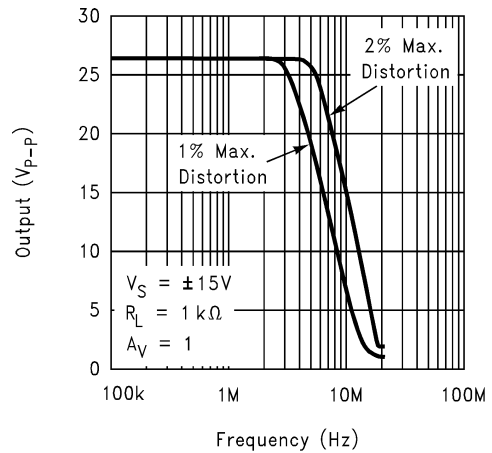


Figure 5-104. Undistorted Output Swing vs Frequency

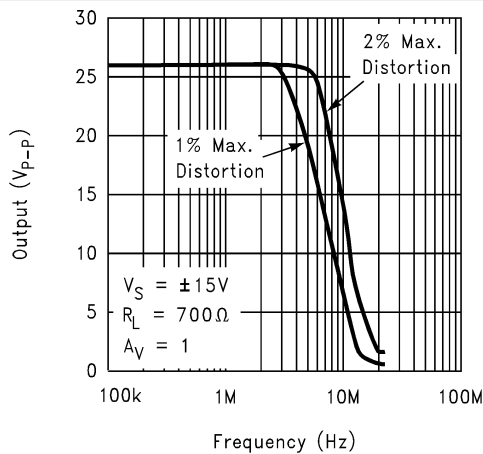


Figure 5-105. Undistorted Output Swing vs Frequency

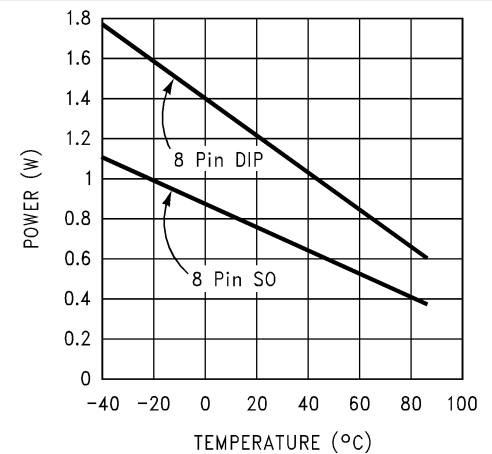


Figure 5-106. Total Power Dissipation vs Ambient Temperature

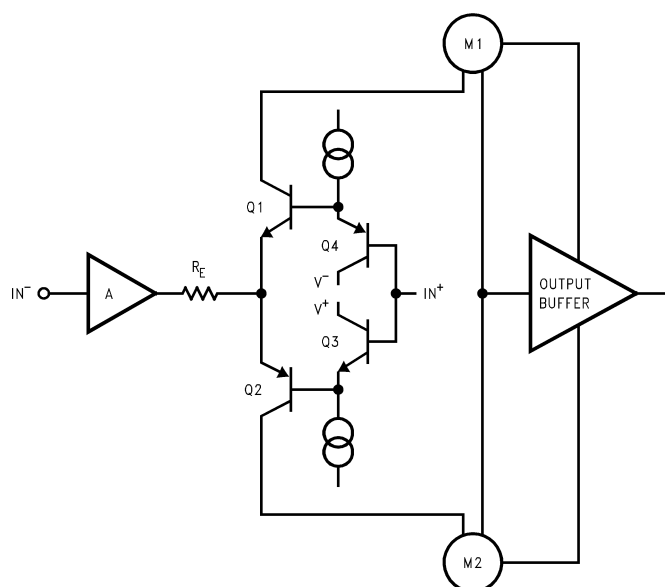
6 Detailed Description

6.1 Overview

The LM6171 is a high-speed, unity-gain-stable voltage-feedback amplifier. The device consumes only 2.5 mA of supply current while providing a gain-bandwidth product of 100 MHz and a slew rate of 3600 V/ μ s. The LM6171 has additional features, such as low differential gain and phase, and high output current. The LM6171 is a great choice in high-speed circuits.

The LM6171 is a true voltage-feedback amplifier. Unlike current-feedback amplifiers (CFAs) with a low inverting input impedance and a high noninverting input impedance, both inputs of voltage-feedback amplifiers (VFAs) have high-impedance nodes. The low-impedance inverting input in CFAs couples with a feedback capacitor and causes oscillation. As a result, CFAs cannot be used in traditional op-amp circuits, such as photodiode amplifiers, I-to-V converters, and integrators.

6.2 Functional Block Diagram



6.3 Feature Description

6.3.1 Circuit Operation

The class AB input stage in the LM6171 is fully symmetrical and has a similar slewing characteristic to the current feedback amplifiers. In the [Section 6.2](#), Q1 through Q4 form the equivalent of the current feedback input buffer, R_E forms the equivalent of the feedback resistor, and stage A buffers the inverting input. The triple-buffered output stage isolates the gain stage from the load to provide low output impedance.

6.3.2 Slew Rate

The slew rate of the LM6171 is determined by the current available to charge and discharge an internal high impedance node capacitor. The current is the differential input voltage divided by the total degeneration resistor R_E . Therefore, the slew rate is proportional to the input voltage level, and higher slew rates are achievable in lower-gain configurations.

When a very fast, large signal pulse is applied to the input of an amplifier, some overshoot or undershoot occurs. By placing an external series resistor, such as 1 k Ω , to the input of the LM6171, the bandwidth is reduced to help reduce overshoot.

6.4 Device Functional Modes

The LM6171 has a single functional mode and can be used with both single-supply or split power-supply configurations. The power-supply voltage must be greater than 9 V (± 4.5 V) and less than 33 V (± 16.5 V).

7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

7.1.1 Compensation for Input Capacitance

The combination of an amplifier input capacitance and gain setting resistors adds a pole that can cause peaking or oscillation. To solve this problem, use a feedback capacitor with the following value to cancel that pole:

$$C_F > \frac{R_G \times C_{IN}}{R_F} \quad (1)$$

For the LM6171, a feedback capacitor of 2 pF is recommended. [Figure 7-1](#) illustrates the compensation circuit.

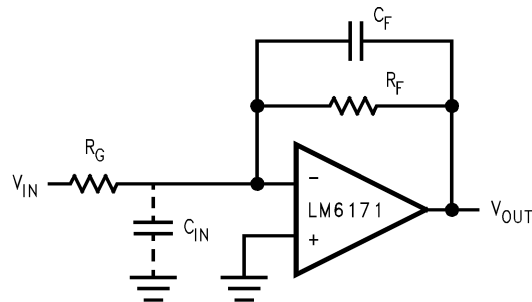


Figure 7-1. Compensating for Input Capacitance

7.1.2 Power Supply Bypassing

Bypassing the power supply is necessary to maintain low power-supply impedance across frequency. Individually bypass both positive and negative power supplies by placing 0.01- μF ceramic capacitors directly to power-supply pins and 2.2- μF tantalum capacitors close to the power-supply pins.

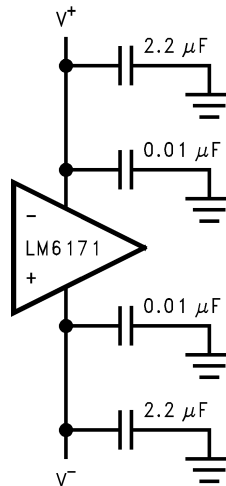


Figure 7-2. Power Supply Bypassing

7.1.3 Termination

In high-frequency applications, reflections occur if signals are not properly terminated. [Figure 7-3](#) shows a properly terminated signal and [Figure 7-4](#) shows an improperly terminated signal.

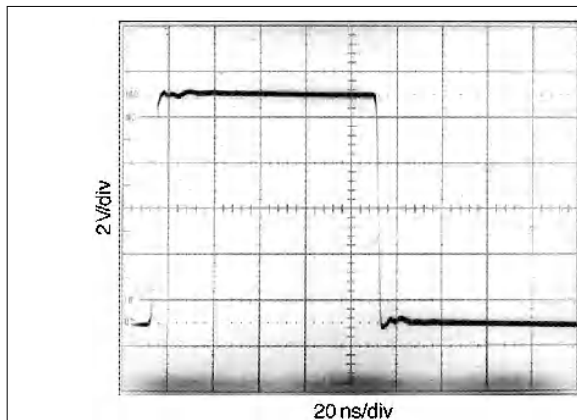


Figure 7-3. Properly Terminated Signal

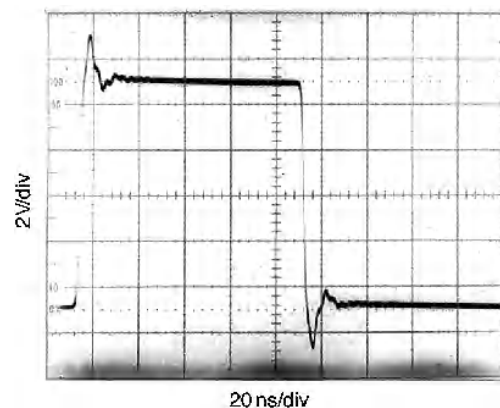


Figure 7-4. Improperly Terminated Signal

To minimize reflection, use coaxial cable with matching characteristic impedance to the signal source. Terminate the other end of the cable with the same value terminator or resistor. For commonly used cables, RG59 has a 75- Ω characteristic impedance, and RG58 has a 50- Ω characteristic impedance.

7.1.4 Driving Capacitive Loads

Amplifiers driving capacitive loads can oscillate or have ringing at the output. To eliminate oscillation or reduce ringing, place an isolation resistor as shown in Figure 7-5. The combination of the isolation resistor and the load capacitor forms a pole to increase stability by adding more phase margin to the overall system. The desired performance depends on the value of the isolation resistor; the bigger the isolation resistor, the more damped the pulse response becomes. For the LM6171, a 50-Ω isolation resistor is recommended for initial evaluation. Figure 7-6 shows the LM6171 driving a 200-pF load with the 50-Ω isolation resistor.

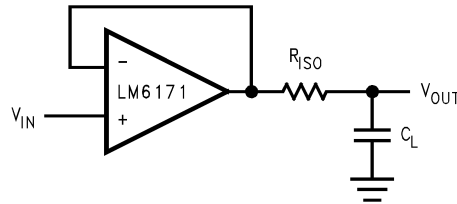


Figure 7-5. Isolation Resistor Used to Drive Capacitive Load

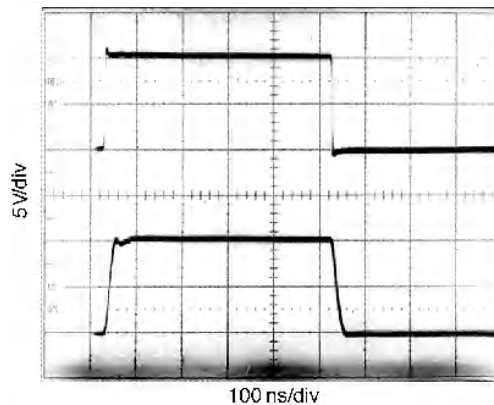


Figure 7-6. The LM6171 Driving a 200-pF Load With a 50-Ω Isolation Resistor

7.1.5 Using Probes

Active (FET) probes are an excellent choice for taking high-frequency measurements because of a wide bandwidth, high input impedance, and low input capacitance. However, the probe ground leads provide a long ground loop that produces errors in measurement. Instead, ground the probes directly by removing the ground leads and probe jackets and using scope probe jacks.

7.1.6 Components Selection and Feedback Resistor

In high-speed applications, keep all component leads short because wires are inductive at high frequency. For discrete components, choose carbon composition-type resistors and mica-type capacitors. Surface-mount components are preferred over discrete components for minimum inductive effect.

Large values of feedback resistors can couple with parasitic capacitance and cause undesirable effects such as ringing or oscillation in high-speed amplifiers. For the LM6171, a feedback resistor of 510 Ω gives optimized performance.

7.2 Typical Applications

7.2.1 Fast Instrumentation Amplifier

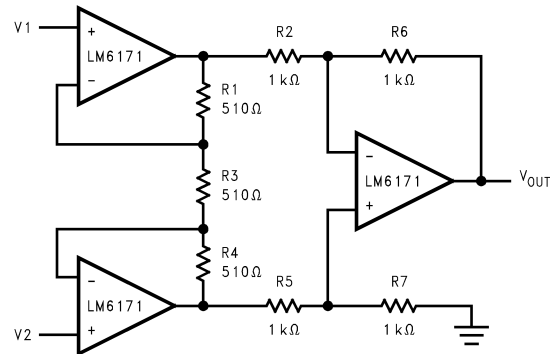


Figure 7-7. Fast Instrumentation Amplifier

$$V_{IN} = V2 - V1$$

if $R6 = R2$, $R7 = R5$ and $R1 = R4$

$$\frac{V_{OUT}}{V_{IN}} = \frac{R6}{R2} \left(1 + 2 \frac{R1}{R3} \right) = 3$$

7.2.2 Multivibrator

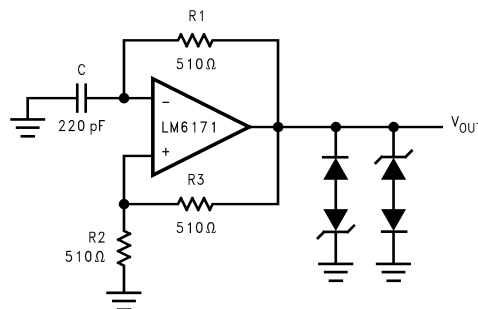


Figure 7-8. Multivibrator

$$f = \frac{1}{2 \left(R1C \ln \left[1 + 2 \frac{R2}{R3} \right] \right)}$$

$$f = 4 \text{ MHz}$$

7.2.3 Pulse Width Modulator

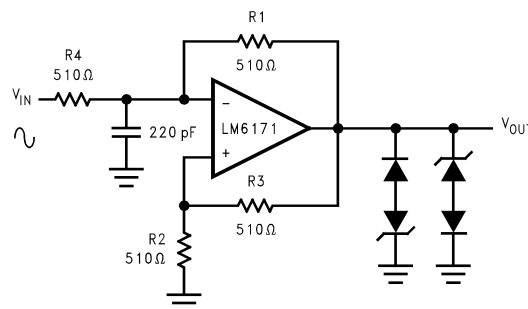


Figure 7-9. Pulse Width Modulator

7.3 Power Supply Recommendations

7.3.1 Power Dissipation

The maximum power allowed to dissipate in a device is defined as:

$$P_D = \frac{T_{J(max)} - T_A}{\theta_{JA}} \quad (2)$$

where

- P_D is the power dissipation in a device
- $T_{J(max)}$ is the maximum junction temperature
- T_A is the ambient temperature
- θ_{JA} is the thermal resistance of a particular package

For example, for the LM6171 in a SOIC-8 package, the maximum power dissipation at 25°C ambient temperature is 730 mW.

Thermal resistance, θ_{JA} , depends on parameters such as die size, package size, and package material. The smaller the die size and package, the higher θ_{JA} becomes. The 8-pin PDIP package has a lower thermal resistance (108°C/W) than the 8-pin SOIC-8 (172°C/W). Therefore, for higher dissipation capability, use an 8-pin PDIP package.

The total power dissipated in a device can be calculated as:

$$P_D = P_Q + P_L \quad (3)$$

where

- P_Q = the quiescent power dissipated in a device with no load connected at the output.
 - P_Q = supply current × total supply voltage with no load
- P_L = the power dissipated in the device with a load connected at the output; P_L is not the power dissipated by the load.
 - P_L = output current × (voltage difference between supply voltage and output voltage of the same supply)

For example, the total power dissipated by the LM6171 with $V_S = \pm 15$ V, and the output voltage of 10 V into a 1-kΩ load resistor (one end tied to ground) is:

$$\begin{aligned} P_D &= P_Q + P_L \\ &= (2.5 \text{ mA}) \times (30 \text{ V}) + (10 \text{ mA}) \times (15 \text{ V} - 10 \text{ V}) \\ &= 75 \text{ mW} + 50 \text{ mW} \\ &= 125 \text{ mW} \end{aligned}$$

7.4 Layout

7.4.1 Layout Guidelines

7.4.1.1 Printed Circuit Boards and High-Speed Op Amps

There are many things to consider when designing a printed circuit board (PCB) for high-speed op amps. Without proper caution, excessive ringing, oscillation, and other degraded ac performance in high-speed circuits can be frustrating. As a rule, keep the signal traces short and wide to provide low inductance and low-impedance paths. Ground any unused board space to reduce stray signal pickup. Also ground any critical components at a common point to eliminate voltage drop. Sockets add capacitance to the board and can affect frequency performance. If possible, solder the amplifier directly into the PCB without using any socket.

8 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

8.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.2 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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8.3 Trademarks

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PAL® is a registered trademark of and used under license from Advanced Micro Devices, Inc..

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8.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.5 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision C (March 2013) to Revision D (November 2023)	Page
• Updated the numbering format for tables, figures, and cross-references throughout the document.....	1
• Added the <i>Pin Configuration and Functions, Specifications, ESD Ratings, Thermal Information, Detailed Description, Application and Implementation, Power Supply Recommendations, Layout, Device and Documentation Support, and Mechanical, Packaging, and Orderable Information</i> sections.....	1
• Changed wide unity-gain bandwidth product from 100 MHz to 76 MHz in <i>Features</i>	1
• Changed –3-dB frequency from 62 MHz to 75 MHz in <i>Features</i>	1
• Deleted text stating that LM6171 is developed in TI's vertically integrated process.....	1
• Changed <i>Operating Ratings</i> to <i>Recommended Operating Conditions</i> and moved Thermal Resistance content to new <i>Thermal Information</i> section	3
• Deleted ESD information and footnote from <i>Absolute Maximum Ratings</i> and moved to <i>ESD Ratings</i>	3
• Deleted footnote from <i>Recommended Operating Conditions</i>	3
• Changed DC and AC specifications tables to <i>Electrical Characteristics: ±15 V</i>	4
• Changed LM6171A unity-gain bandwidth from 100 MHz to 76 MHz in <i>Electrical Characteristics: ±15 V</i>	4
• Changed LM6171A –3-dB freq for $A_V = +1$ from 160 MHz to 200 MHz in <i>Electrical Characteristics: ±15 V</i>	4
• Changed LM6171A –3-dB freq for $A_V = +2$ from 62 MHz to 75 MHz in <i>Electrical Characteristics: ±15 V</i>	4
• Changed LM6171A phase margin from 40° to 58° in <i>Electrical Characteristics: ±15 V</i>	4
• Changed LM6171A settling time from 48 ns to 21 ns in <i>Electrical Characteristics: ±15 V</i>	4
• Changed LM6171A propagation delay from 6 ns to 4.1 ns in <i>Electrical Characteristics: ±15 V</i>	4
• Changed 5 V DC and AC specifications tables to <i>Electrical Characteristics: ±5 V</i>	6
• Changed LM6171A input common-mode voltage from ±3.7 V to ±3.2 V in <i>Electrical Characteristics: ±5 V</i>	6
• Changed LM6171A –3-dB frequency for $A_V = +1$ from 130 MHz to 190 MHz in <i>Electrical Characteristics: ±5 V</i>	6
• Changed LM6171A –3-dB frequency for $A_V = +2$ from 45 MHz to 75 MHz in <i>Electrical Characteristics: ±5 V</i> .	6
• Changed LM6171A settling time from 60 ns to 25 ns in <i>Electrical Characteristics: ±5 V</i>	6
• Changed LM6171A propagation delay from 8 ns to 4.5 ns in <i>Electrical Characteristics: ±5 V</i>	6
• Added new <i>Typical Characteristics</i> section for LM6171A.....	8
<hr/>	
Changes from Revision B (March 2013) to Revision C (March 2013)	Page
• Changed National Semiconductor data-sheet layout to Texas Instruments format.....	1

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM6171AIM/NOPB	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-40 to 85	LM61 71AIM
LM6171AIMX/NOPB	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(L61AIM, LM61) 71AIM
LM6171AIMX/NOPB.Z	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(L61AIM, LM61) 71AIM
LM6171BIM/NOPB	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-40 to 85	LM61 71BIM
LM6171BIMX/NOPB	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-40 to 85	LM61 71BIM
LM6171BIN/NOPB	Active	Production	PDIP (P) 8	40 TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	-40 to 85	LM6171 BIN
LM6171BIN/NOPB.Z	Active	Production	PDIP (P) 8	40 TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	-40 to 85	LM6171 BIN

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM6171AIMX/NOPB	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM6171AIMX/NOPB	SOIC	D	8	2500	353.0	353.0	32.0

TUBE


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
LM6171BIN/NOPB	P	PDIP	8	40	502	14	11938	4.32
LM6171BIN/NOPB.Z	P	PDIP	8	40	502	14	11938	4.32



D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed $.006$ [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001 variation BA.

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